

GENERAL DESCRIPTION

This document describes the specifications for the IDTF1162 Zero-Distortion™ RF to IF Downconverting Mixer. This device is part of a series of mixers offered with high side or low side injection options for all UTRA bands. See the Part# Matrix for the details of all devices in this series.

The F1162 dual channel device is designed to operate with a single 5V supply. It is optimized for operation in a Multi-mode, Multi-carrier BaseStation Receiver for RF bands from 2300 - 2700 MHz with Low Side or High Side Injection. IF frequencies from 50 to 500 MHz are supported. Nominally, the device offers +43 dBm Output IP3 with 330 mA of I_{CC} . Alternately one can adjust 4 resistor values and a toggle pin to run the device in low current mode with +38 dBm Output IP3 and 230 mA of I_{CC} .

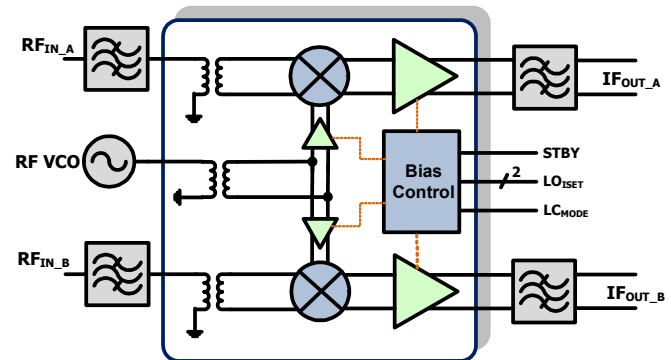
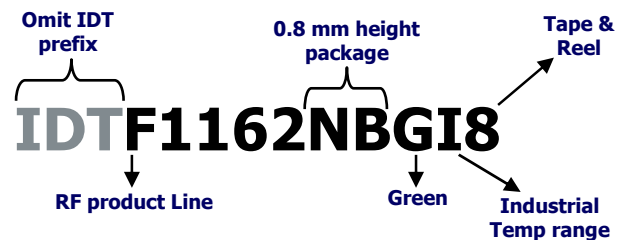
COMPETITIVE ADVANTAGE

In typical basestation receivers the RF to IF mixer dominates the linearity performance for the entire receive system. The Zero-Distortion™ family of mixers dramatically improve the maximum signal levels (IM_3 tones) that the BTS can withstand at a desired Signal to Noise Ratio (SNR.) Alternately, one can run the device in Low Current Mode to reduce Power consumption significantly. Zero-Distortion™ technology allows realization of either benefit.

- ✓ IP3₀: ↑ **11 dB** STD Mode, ↑ **5 dB** LC Mode
- ✓ Dissipation: ↓ **40%** LC, ↓ **15%** STD Mode
- ✓ Allows for higher RF gain improving **Sensitivity**


FEATURES

- Dual Path for Diversity Systems
- Ideal for Multi-Carrier Systems
- 8.9 dB Gain
- Ultra linear **+43 dBm IP3₀**
- Low NF < 10 dB
- 200 Ω output impedance
- Ultra high +13 dBm P1dB₁
- **Pin Compatible** w/existing solutions
- 6x6 36 pin package
- **Constant LO Port Z in STBY mode**
- < 200 nsec settling from Power Down
- Low Current Mode : **I_{CC} = 230 mA**
- Standard Mode: **I_{CC} = 330 mA**
- NOTE production BOM on p. 25

DEVICE BLOCK DIAGRAM

ORDERING INFORMATION

PART# MATRIX

| Part# | RF freq range | UTRA bands | IF freq range | Typ. Gain | Injection |
|--------------|--------------------|---|-----------------|------------|-------------|
| F1100 | 698 - 915 | 5,6,8,12,13,14,17,19,20 | 50 - 450 | 8.5 | High Side |
| F1102 | 698 - 915 | 5,6,8,12,13,14,17,19,20 | 50 - 250 | 8.5 | Both |
| F1150 | 1700 - 2200 | 1,2,3,4,9,10, 33, 34,35, 36, 37,39 | 50 - 450 | 8.5 | High Side |
| F1152 | 1400 - 2200 | 1,2,3,4,9,10,11 ¹ , 21 ¹ , 24 ¹ , 33, 34,35, 36, 37,39 | 50 - 350 | 8.5 | Low Side |
| F1162 | 2300 - 2700 | 7,38,40,41 | 50 - 500 | 8.9 | Both |

1 - with High side injection

ABSOLUTE MAXIMUM RATINGS

| | |
|---|------------------------------------|
| VCC to GND | -0.3V to +5.5V |
| STBY, LC _{MODE} | -0.3V to (VCC ₋ + 0.3V) |
| IF_A+, IF_B+, IF_A-, IF_B-, LO1_ADJ, LO2_ADJ | -0.3V to (VCC ₋ + 0.3V) |
| LO_IN, LO_IN_ALT, RF_A, RF_B | -0.3V to +0.3V |
| IF_BiasA, IF_BiasB to GND | -0.3V to +0.3V |
| RF Input Power (RF_IN[A+, A-, B+, B-]) | +20dBm |
| Continuous Power Dissipation | 2.2W |
| θ_{JA} (Junction – Ambient) | +35°C/W |
| θ_{JC} (Junction – Case) The Case is defined as the exposed paddle | +2.5°C/W |
| Operating Temperature Range (Case Temperature) | T _C = -40°C to +100°C |
| Maximum Junction Temperature | 150°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature (soldering, 10s) . | +260°C |

Stresses above those listed above may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RF to IF Dual Downconverting Mixer
2300 - 2700 MHz F1162NBGI
IDTF1162 SPECIFICATION

Specifications apply at $V_{CC} = +5.00V$, $T_C = +25^{\circ}C$, $F_{RF} = 2600\text{ MHz}$, $F_{IF} = 400\text{ MHz}$, Low Side Injection, $P_{LO} = 0\text{ dBm}$, $STBY = GND$, $LC_{MODE} = V_{IH}$ (STD Mode), EVKit BOM = Standard Mode, Transformer Loss included (not de-embedded) unless otherwise noted.

| Parameter | Comment | Symbol | min | typ | max | units |
|-----------------------------|---|------------------|-------------|--------------|------------------------|-----------|
| Logic Input High | For Standby, LC_{MODE} Pins | V_{IH} | 2 | | | V |
| Logic Input Low | For Standby, LC_{MODE} Pins | V_{IL} | | | 0.8 | V |
| Logic Current | For Standby Pin | I_{IH}, I_{IL} | -30 | | +30 | μA |
| Logic Current | For LC_{MODE} Pin | I_{IH}, I_{IL} | -100 | | -20 | μA |
| Supply Voltage(s) | All V_{CC} pins | V_{CC} | | 4.75 to 5.25 | | V |
| Operating Temperature Range | Case Temperature | T_{CASE} | | -40 to +100 | | degC |
| Supply Current | Total V_{CC} , STD Mode <ul style="list-style-type: none"> ▪ Total Both Channels | I_{STD} | | 330 | 375¹ | mA |
| Supply Current | Total V_{CC} , LC Mode <ul style="list-style-type: none"> ▪ $LC_{MODE} = GND$ ▪ EVkit BOM = LC Mode ▪ Total Both Channels | I_{LC} | | 230 | 260 | mA |
| Supply Current | Standby Mode <ul style="list-style-type: none"> ▪ $STBY = V_{IH}$ ▪ $LC_{MODE} > V_{IH}$ (STD Mode) ▪ Total Both Channels | I_{STBY} | | 23 | 30 | mA |
| RF Freq Range | Operating Range | F_{RF} | | 2300 to 2700 | | MHz |
| IF Freq Range | Operating Range | F_{IF} | | 50 to 500 | | MHz |
| LO Freq Range | Operating Range | F_{LO} | | 1800 to 2900 | | MHz |
| LO Power | Operating Range | P_{LO} | | -6 to +6 | | dBm |
| RF Input Impedance | Single Ended Return Loss ~20 dB | Z_{RF} | | 50 | | Ω |
| IF Output Impedance | Differential Return Loss ~ 15 dB | Z_{IF} | | 200 | | Ω |
| LO port Impedance | Single Ended Return Loss ~15 dB | Z_{LO} | | 50 | | Ω |
| Settling Time | <ul style="list-style-type: none"> • Pin = -13 dBm • Gate STBY from V_{IH} to V_{IL} • Time for IF Signal to settle to within 0.1 dB of final value | T_{SETT} | | 0.150 | | μsec |
| Gain STD Mode | Conversion Gain <ul style="list-style-type: none"> • $F_{RF} = 2300\text{ MHz}$ • $LC_{MODE} = V_{IH}$ • EVkit BOM = STD Mode • $F_{IF} = 400\text{ MHz}$ (Low Side Inj.) | G_{STD} | 7.2 | 8.4 | 9.6 | dB |

IDTF1162 SPECIFICATION (CONTINUED)

| Parameter | Comment | Symbol | min | typ | max | units |
|----------------------------------|---|-----------------|-----------------------|-------------|------------|-------|
| Gain LC Mode | Conversion Gain <ul style="list-style-type: none"> • $F_{RF} = 2700$ MHz • $LC_{MODE} = GND$ • EVKit BOM = LC Mode • $F_{IF} = 200$ MHz (High Side Inj.) | G_{LC} | 6.8 | 7.9 | 9.0 | dB |
| NF STD Mode | Noise Figure <ul style="list-style-type: none"> • RF trace de-embedded • $F_{IF} = 200$ MHz | NF_{STD} | | 9.9 | | dB |
| NF LC Mode | Noise Figure <ul style="list-style-type: none"> • RF trace de-embedded • $LC_{MODE} = GND$, EVKit BOM = LC • $F_{IF} = 200$ MHz | NF_{LC} | | 9.7 | | dB |
| NF w/Blocker | <ul style="list-style-type: none"> ▪ +100 MHz offset blocker ▪ $P_{BLOCKER} = +10$ dBm ▪ $F_{IF} = 250$ MHz | NF_{BLK} | | 23.5 | | dB |
| Output IP3 – STD mode | <ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ 800 KHz Tone Separation | $IP3_{O1}$ | 38² | 43 | | dBm |
| Output IP3 – LC mode | <ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ $F_{IF} = 200$ MHz (Low Side Inj.) ▪ $F_{RF} = 2600$ MHz ▪ 800 KHz Tone Separation ▪ $LC_{MODE} = GND$ ▪ EVKit BOM = LC Mode | $IP3_{O3}$ | 33.5 | 37.7 | | dBm |
| Output IP3 – High Side Injection | <ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ 800 KHz Tone Separation ▪ $F_{IF} = 154$ MHz (High Side Inj.) ▪ $F_{RF} = 2600$ MHz ▪ Modified LC mode BOM (p. 26) | $IP3_{O2}$ | | 43 | | dBm |
| 2RF – 2LO rejection | <ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm ▪ Frequency = $F_{RF} - \frac{1}{2} F_{IF}$ | 2x2 | | -68 | | dBc |
| 1 dB Compression – STD Mode | <ul style="list-style-type: none"> ▪ Input referred ▪ 400 MHz IF | $P1dB_{I1}$ | 11 | 11.9 | | dBm |
| 1 dB Compression – LC Mode | <ul style="list-style-type: none"> ▪ $LC_{MODE} = GND$ ▪ EVKit BOM = LC Mode ▪ $F_{IF} = 200$ MHz (Low Side Inj.) | $P1dB_{I2}$ | 8 | 10.2 | | dBm |
| Gain Comp. w/blocker | <ul style="list-style-type: none"> ▪ Blocker → unmodulated tone ▪ $P_{IN} = +8$ dBm, +100 MHz offset ▪ Signal Pin Tone = -20 dBm ▪ Measure ΔG of signal ▪ $F_{IF} = 250$ MHz | ΔG_{AC} | | 0.15 | | dB |
| Channel Isolation | IF_B Pout vs. IF_A w/ RF_A input | ISO_C | | 63 | | dB |
| LO to IF leakage | LO Frequency = 2200 MHz | ISO_{LI} | | -32 | -23 | dBm |
| RF to IF leakage | $P_{in} = -10$ dBm | ISO_{RI} | | -57 | -43 | dBm |
| LO to RF leakage | <ul style="list-style-type: none"> • LO Frequency = 2345 MHz • Low Current Mode | ISO_{LR} | | -41 | | dBm |

1 – Items in min/max columns in **bold italics** are Guaranteed by Test

2 – All other Items in min/max columns are Guaranteed by Design Characterization

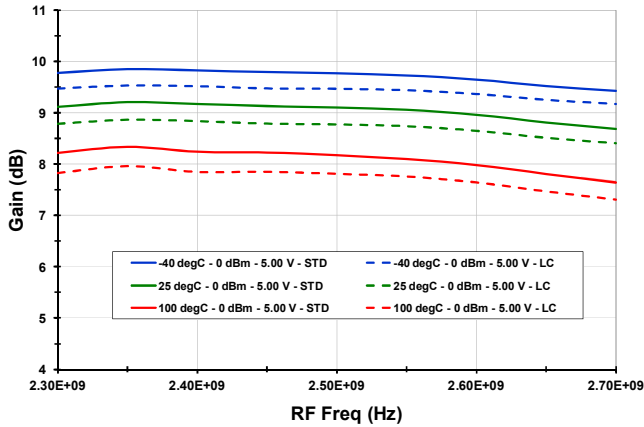
TYPICAL OPERATING CONDITIONS

Unless otherwise Noted, the following Apply to the Typ Ops Graphs

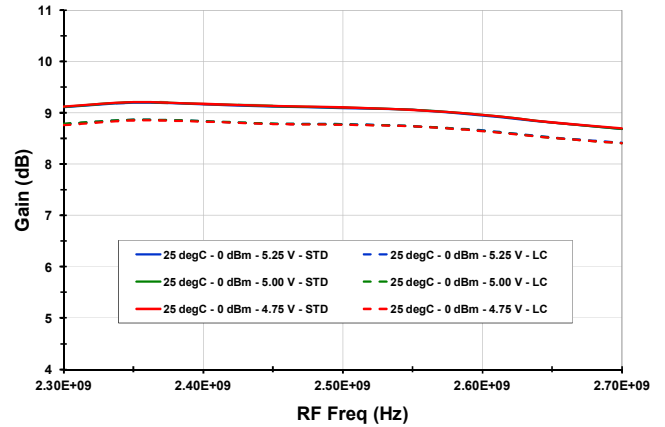
- 800 KHz Tone Spacing
- Low Side injection graphs with 200MHz & 400MHz IF (pages 6 – 14)
- High Side injection graphs with 200MHz & 154MHz IF (pages 15 – 17)
- Average of Channel A & Channel B
- Pin = – 10 dBm per Tone
- LO port = Pin 19 (Main Port)
- Listed Temperatures are Case Temperature (T_C = Case Temperature)
- Where noted, T_A or T_{AMB} = Ambient Temperature

TYPICAL OPERATING CONDITIONS [IF = 200 MHz, Low Side Injection] (-1-)

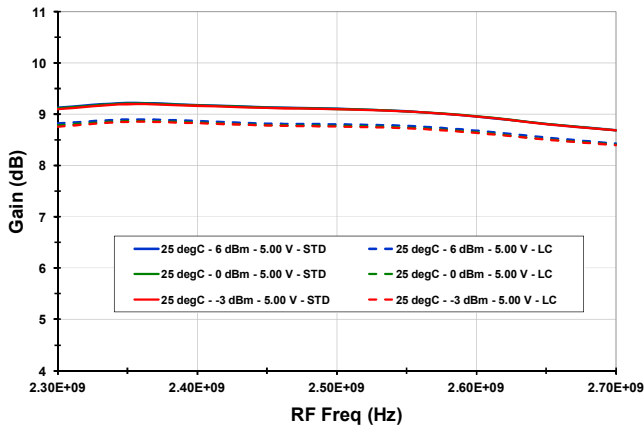
Gain vs. T_{CASE}



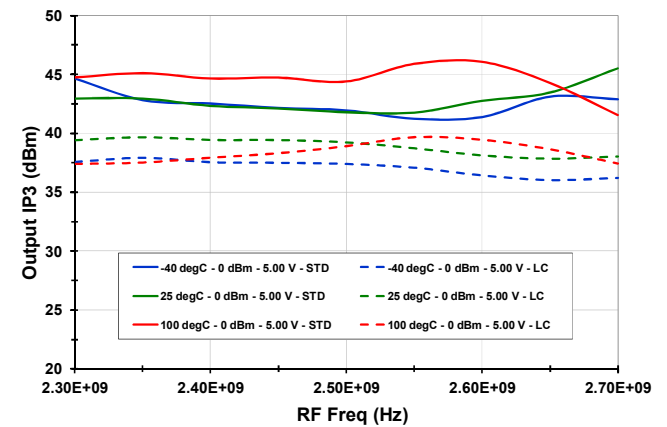
Gain vs. V_{CC}



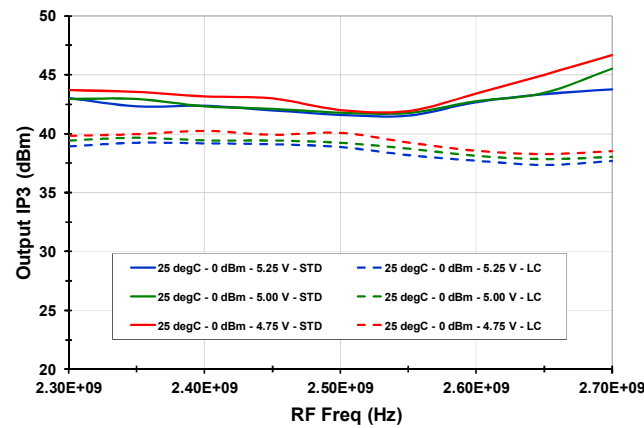
Gain vs. LO Level



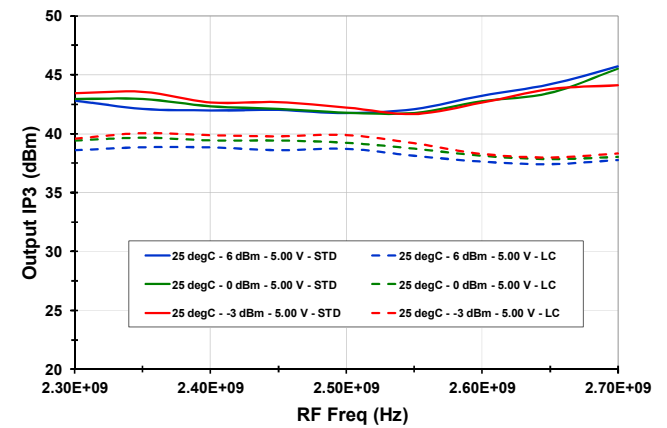
Output IP3 vs. T_{CASE}



Output IP3 vs. V_{CC}

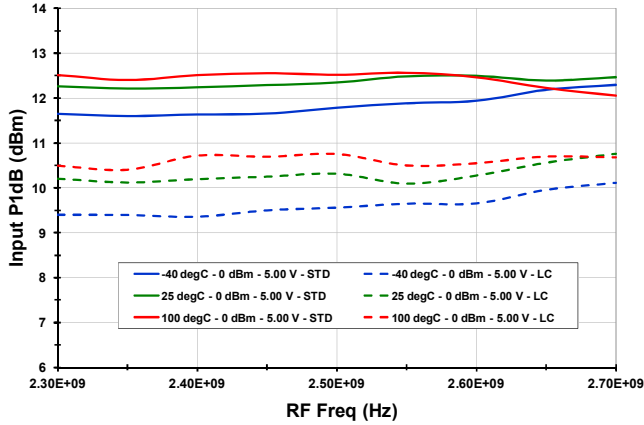


Output IP3 vs. LO Level

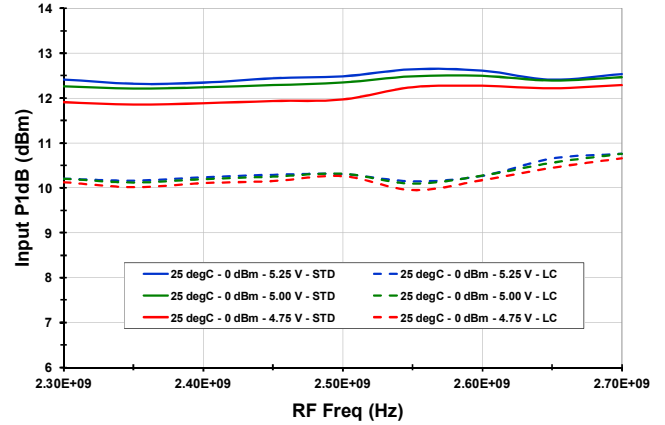


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, Low Side Injection] (-2-)

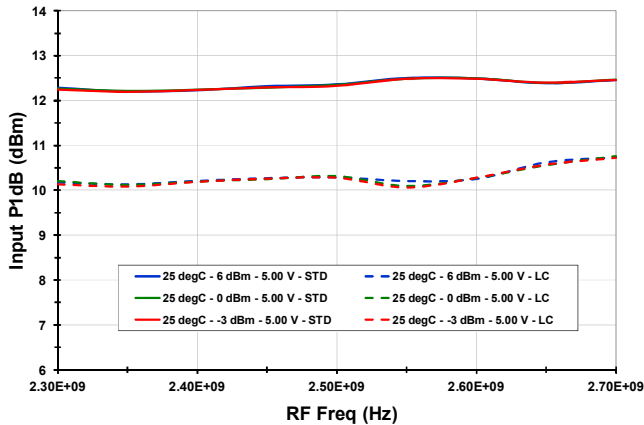
P1dB vs. T_{CASE}



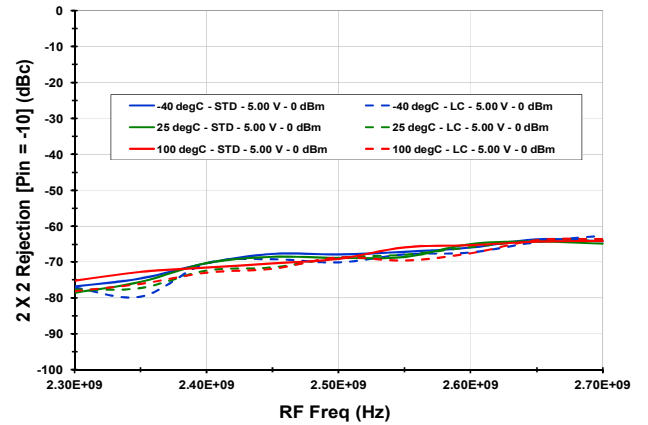
P1dB vs. V_{CC}



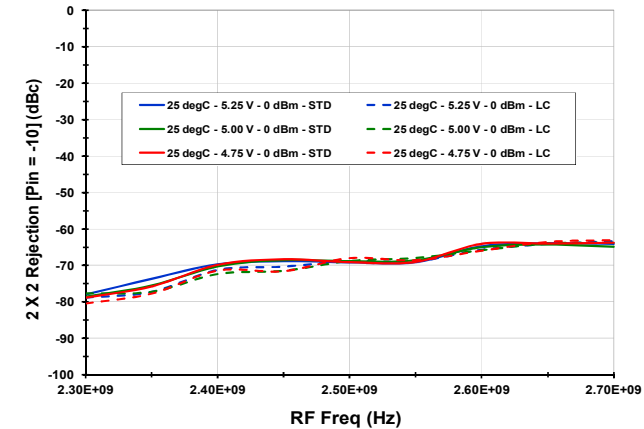
P1dB vs. LO Level



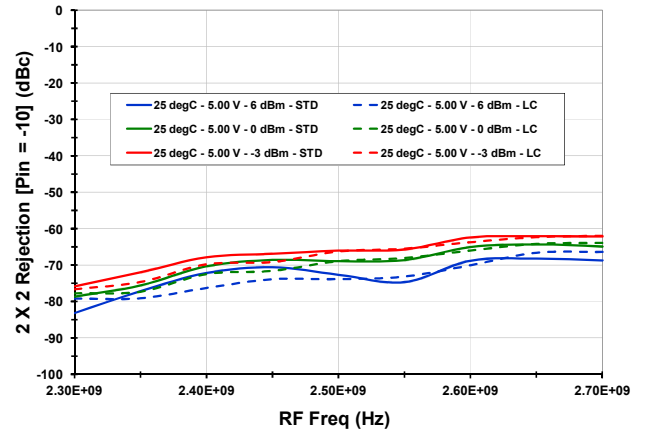
2RF x 2LO rejection vs. T_{CASE}



2RF x 2LO Rejection vs. V_{CC}

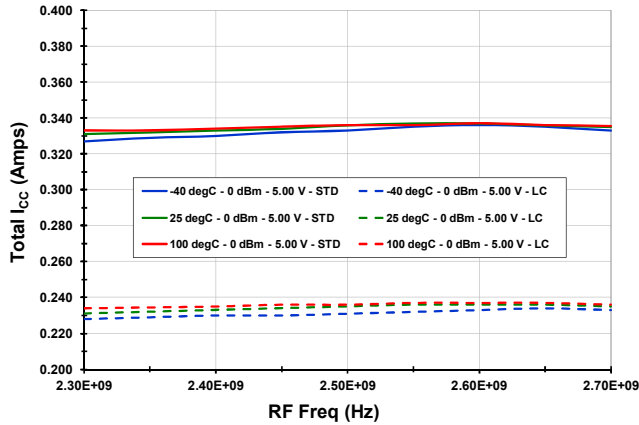


2RF x 2LO Rejection vs. LO Level

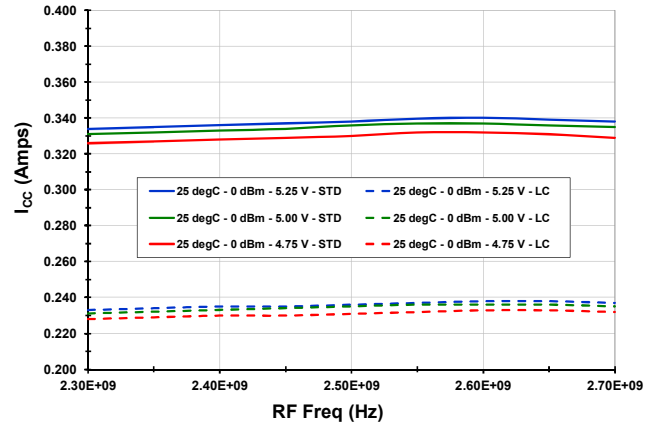


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, Low Side Injection] (-3-)

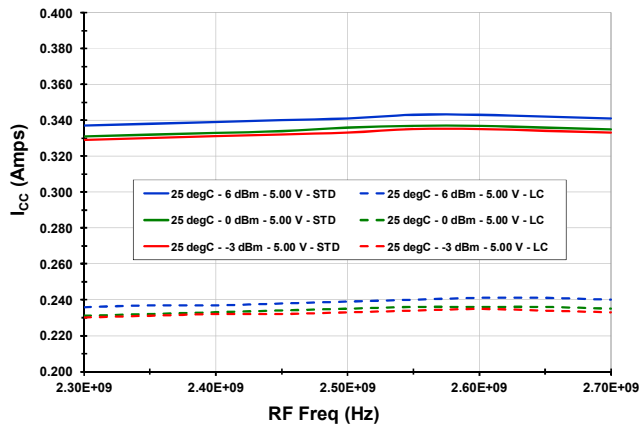
I_{CC} vs. T_{CASE}



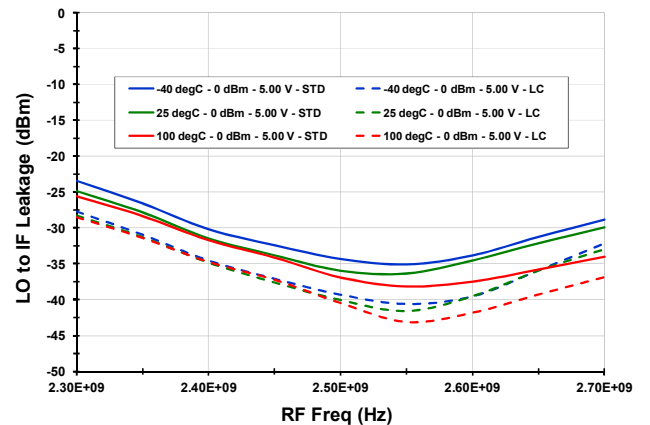
I_{CC} vs. V_{CC}



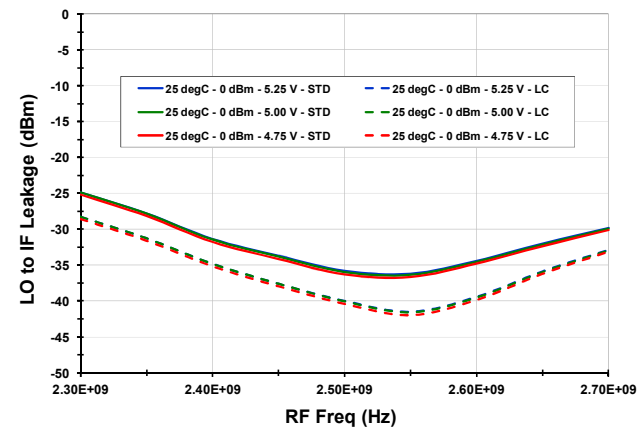
I_{CC} vs. LO Level



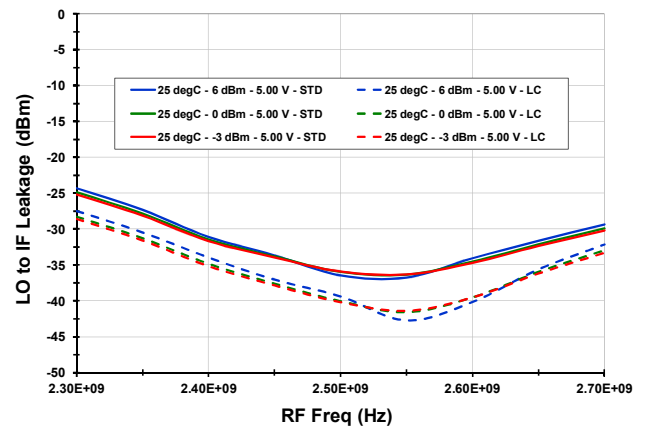
LO-IF Leakage vs. T_{CASE}



LO-IF Leakage vs. V_{CC}

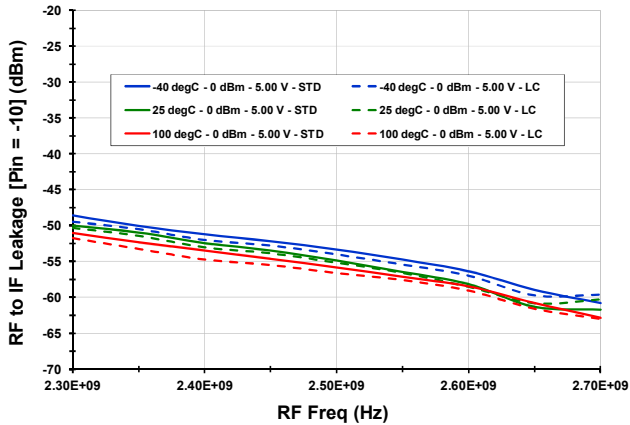


LO-IF Leakage vs. LO Level

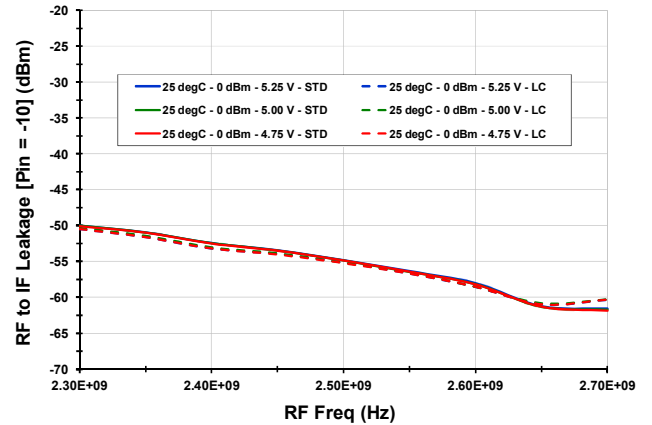


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, Low Side Injection] (-4-)

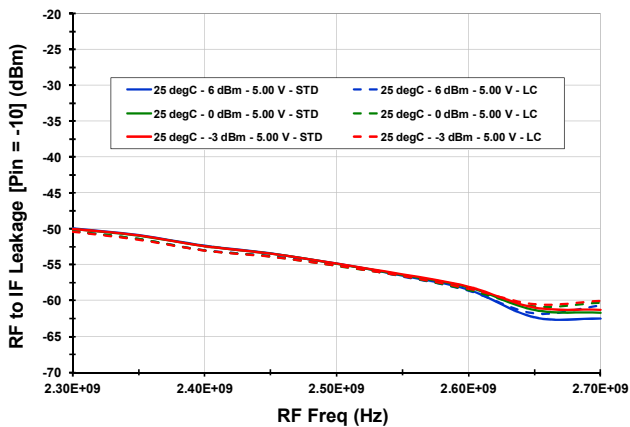
RF-IF Leakage vs. T_{CASE}



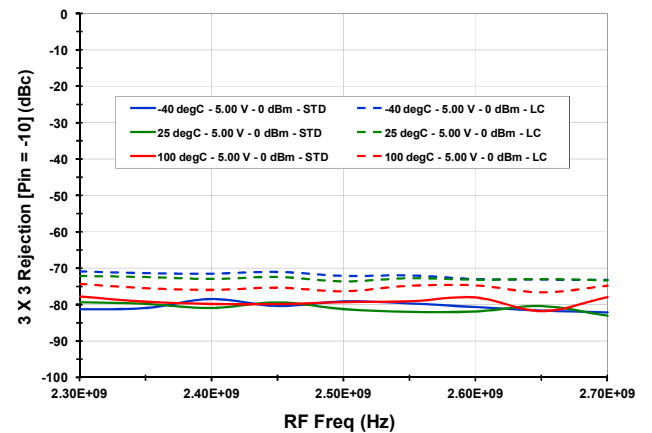
RF-IF Leakage vs. V_{CC}



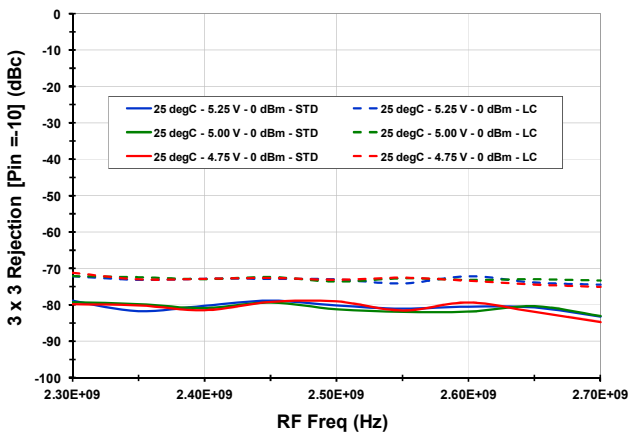
RF-IF Leakage vs. LO Level



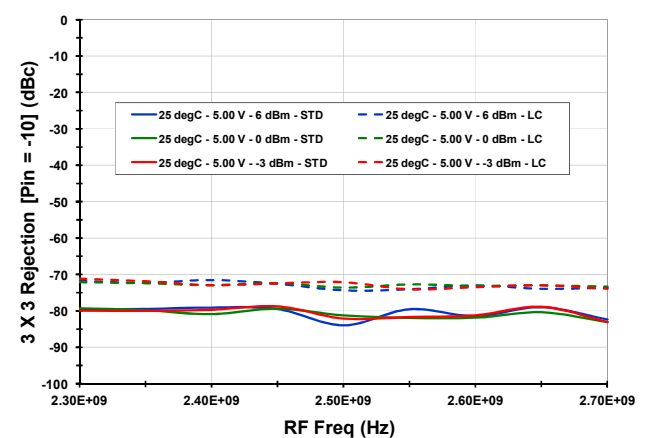
3RF X 3LO Rejection vs. T_{CASE}



3RF X 3LO Rejection vs. V_{CC}



3RF X 3LO Rejection vs. LO Level

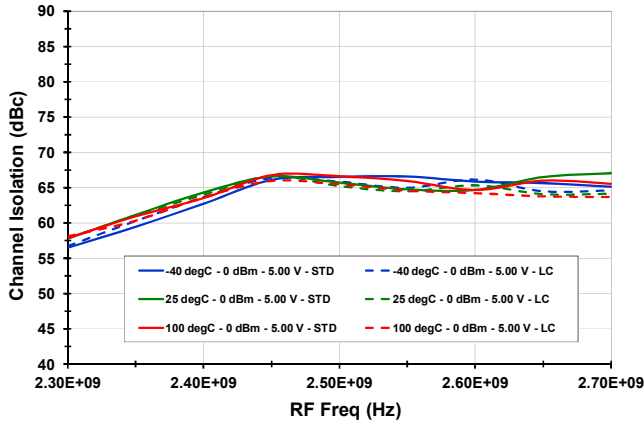


RF to IF Dual Downconverting Mixer

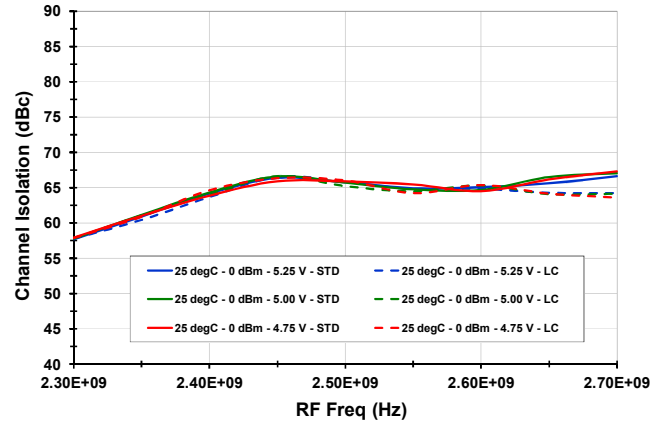
2300 - 2700 MHz F1162NBGI

TYPICAL OPERATING CONDITIONS [IF = 200 MHz, Low Side Injection] (-5-)

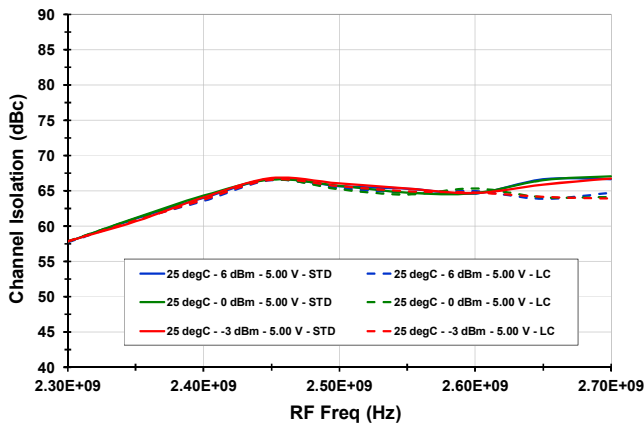
Channel Isolation vs. T_{CASE}



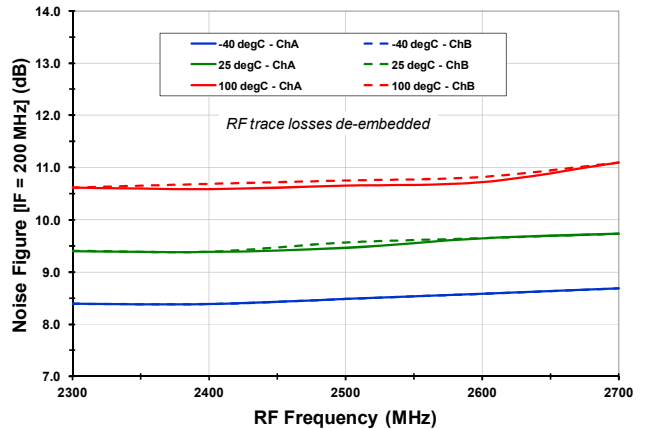
Channel Isolation vs. V_{CC}



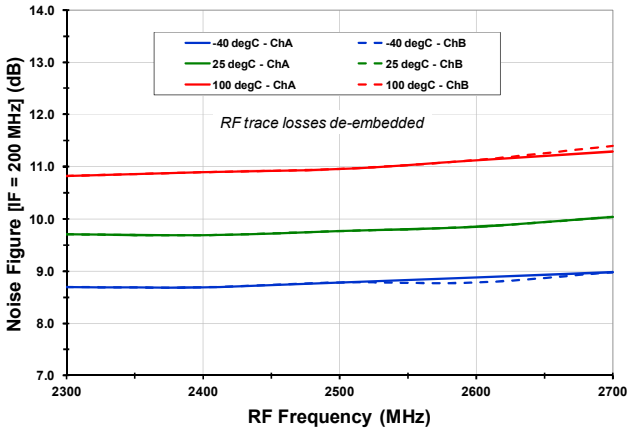
Channel Isolation vs. LO Level



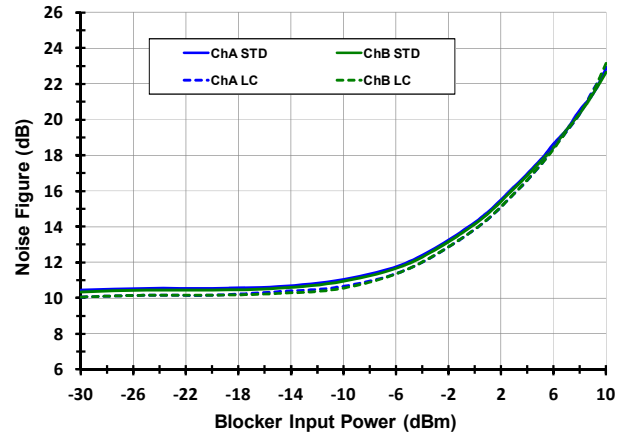
Noise Figure vs. T_{CASE} (LC Mode)



Noise Figure vs. T_{CASE} (STD Mode)



NF vs. Blocker (RF = 2600 MHz, IF = 250 MHz, T_A = 25C)

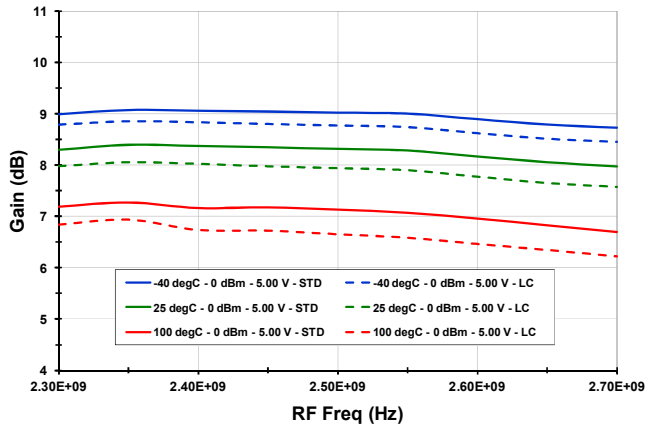


RF to IF Dual Downconverting Mixer

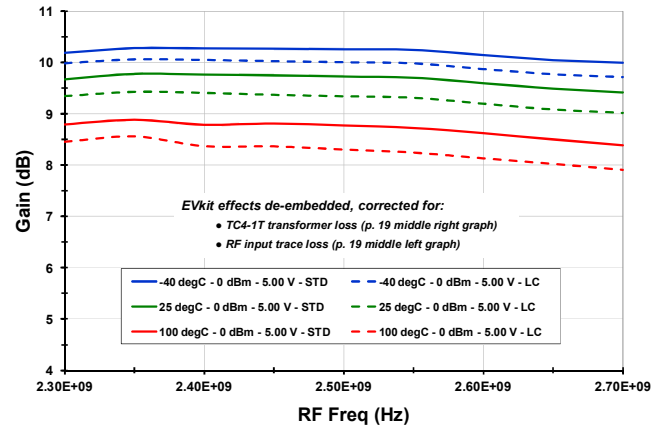
2300 - 2700 MHz F1162NBGI

TYPICAL OPERATING CONDITIONS [IF = 400 MHz, Low Side Injection] (-6-)

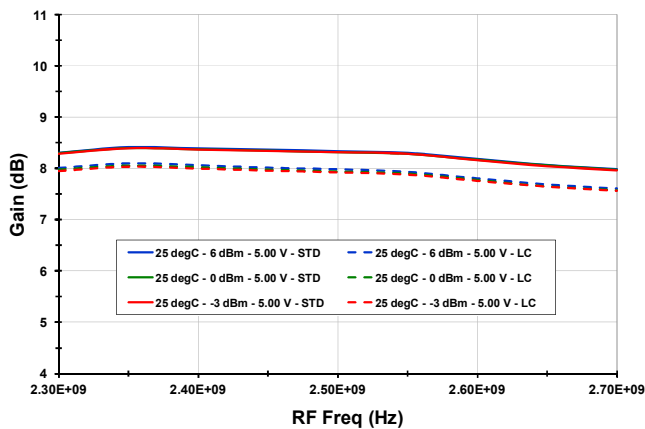
Gain vs. T_{CASE}



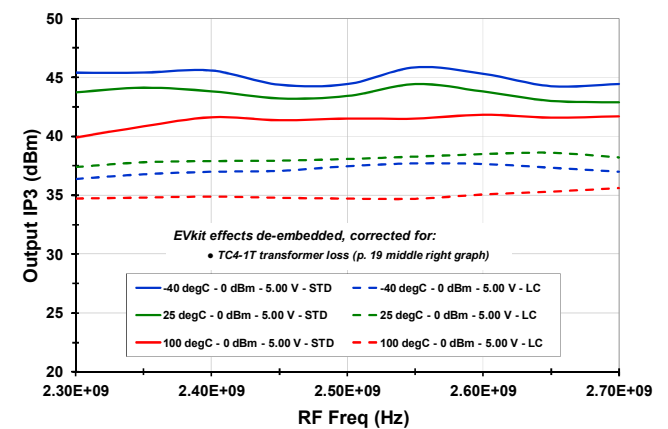
Gain vs. T_{CASE} (EVKIT DE-EMBEDDED)



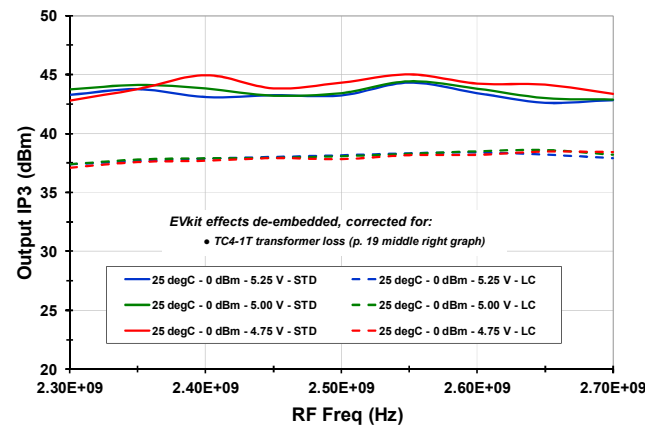
Gain vs. LO Level



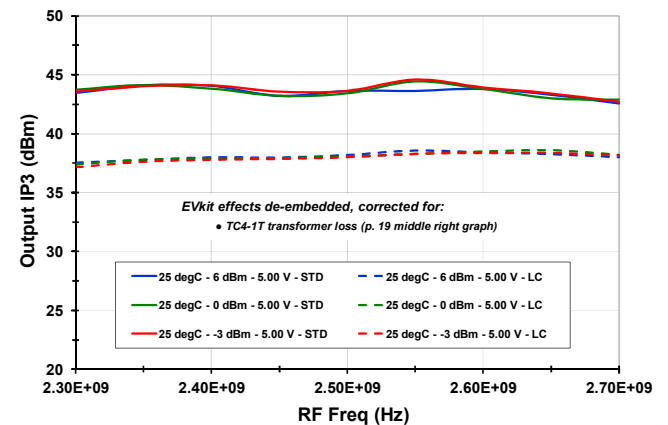
Output IP3 vs. T_{CASE} (EVKIT DE-EMBEDDED)



Output IP3 vs. V_{CC} (EVKIT DE-EMBEDDED)

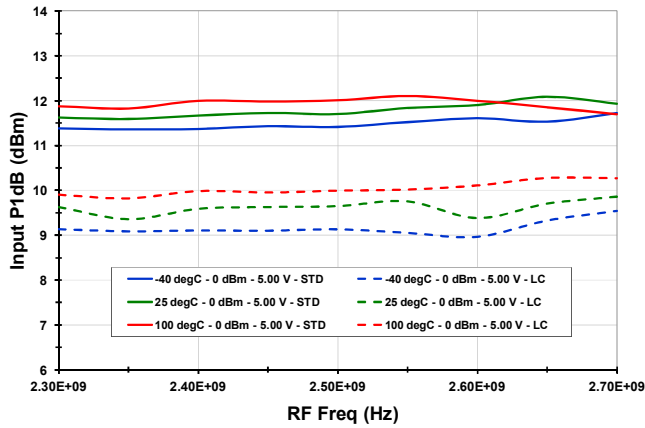


Output IP3 vs. LO Level (EVKIT DE-EMBEDDED)

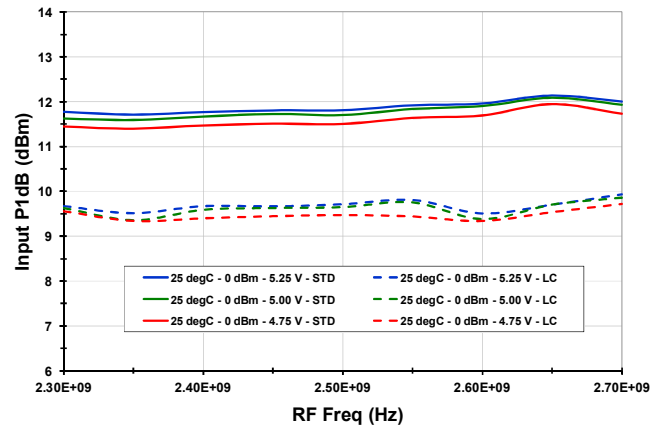


TYPICAL OPERATING CONDITIONS [IF = 400 MHz, Low Side Injection] (-7-)

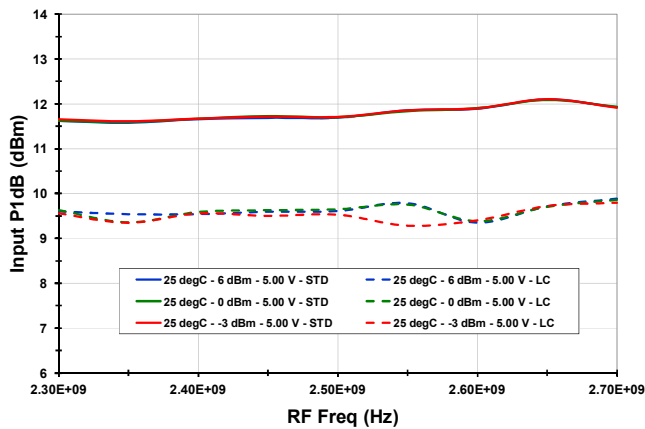
P1dB vs. T_{CASE}



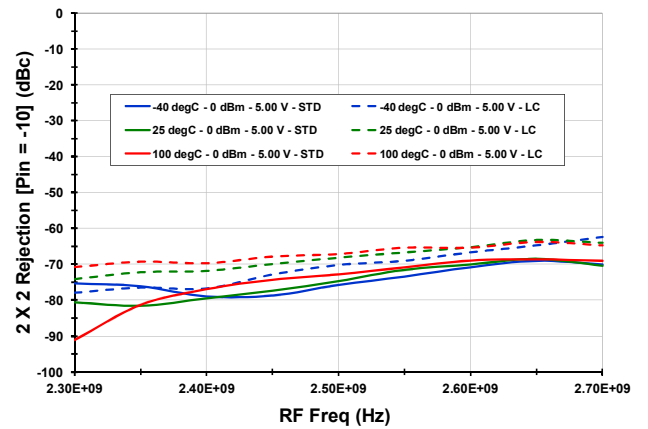
P1dB vs. V_{CC}



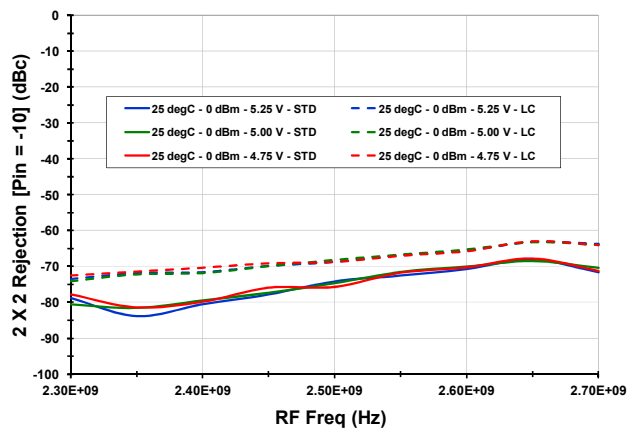
P1dB vs. LO Level



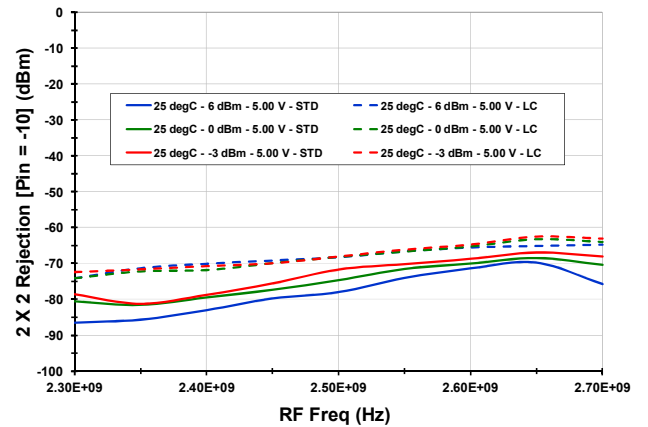
2RF x 2LO rejection vs. T_{CASE}



2RF x 2LO Rejection vs. V_{CC}

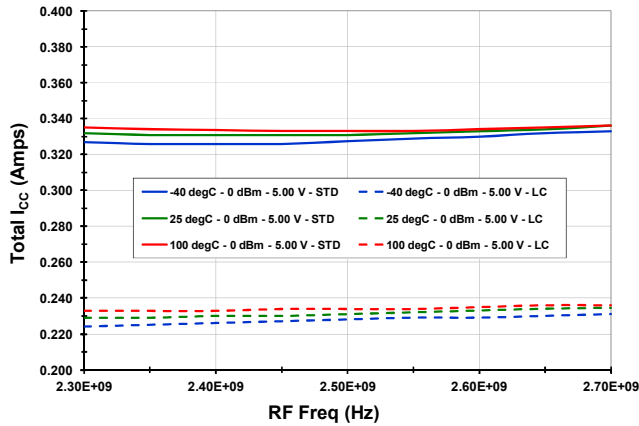


2RF x 2LO rejection vs. LO Level

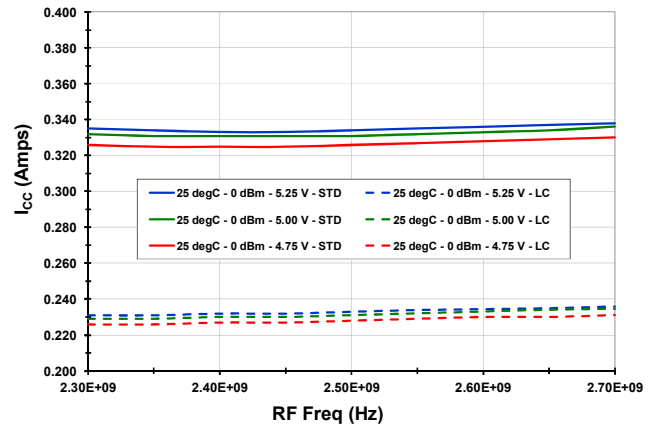


TYPICAL OPERATING CONDITIONS [IF = 400 MHz, Low Side Injection] (-8-)

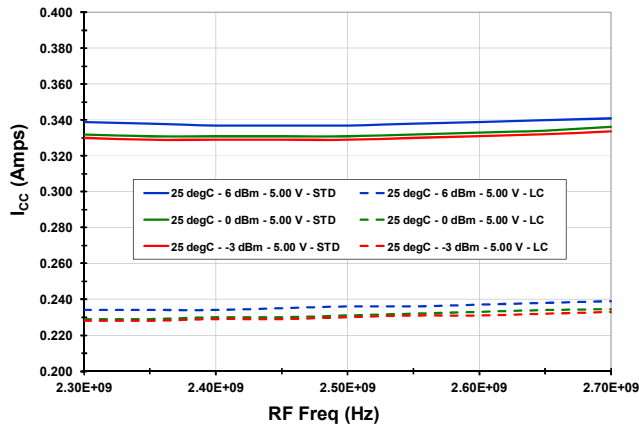
I_{CC} vs. T_{CASE}



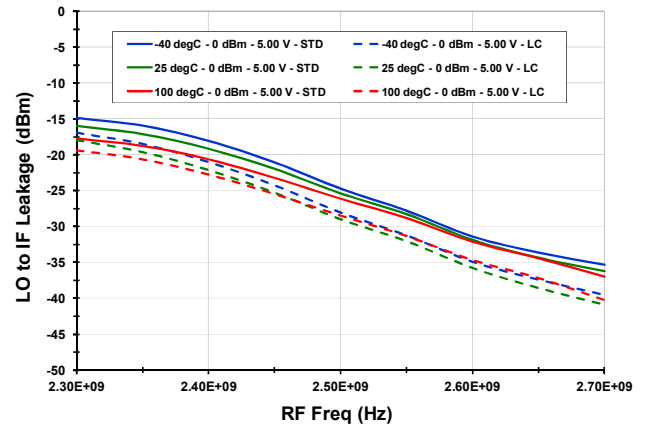
I_{CC} vs. V_{CC}



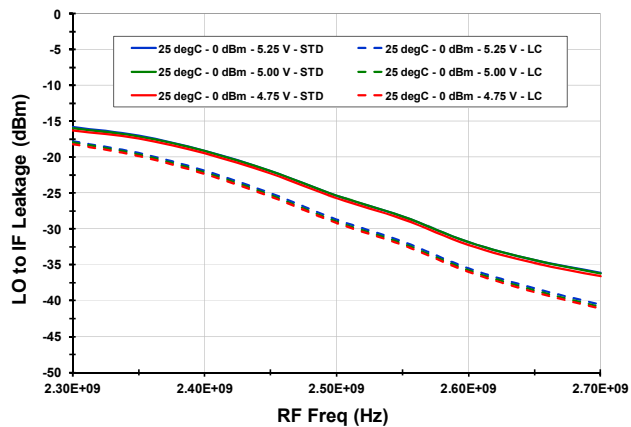
I_{CC} vs. LO Level



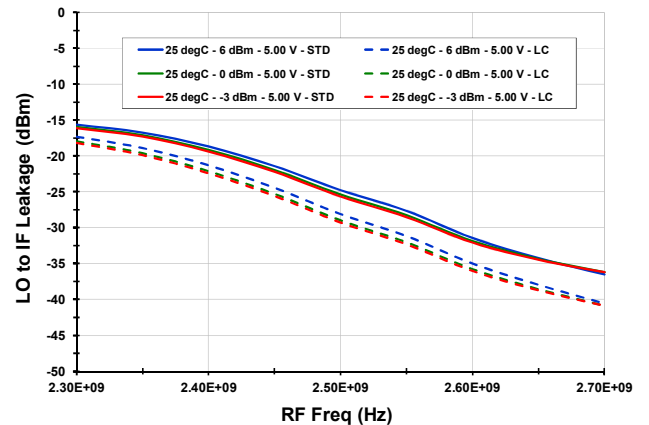
LO-IF Leakage vs. T_{CASE}



LO-IF Leakage vs. V_{CC}



LO-IF Leakage vs. LO Level

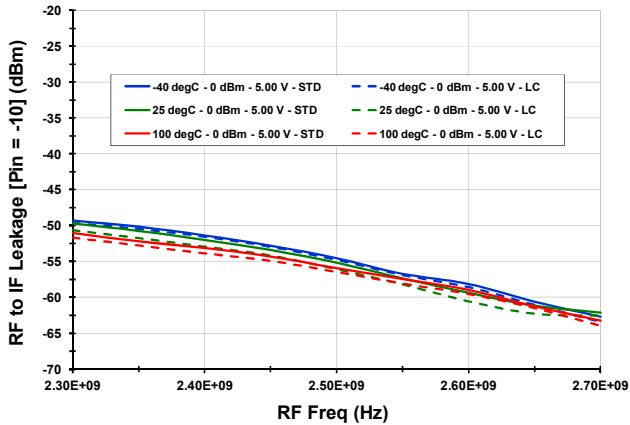


RF to IF Dual Downconverting Mixer

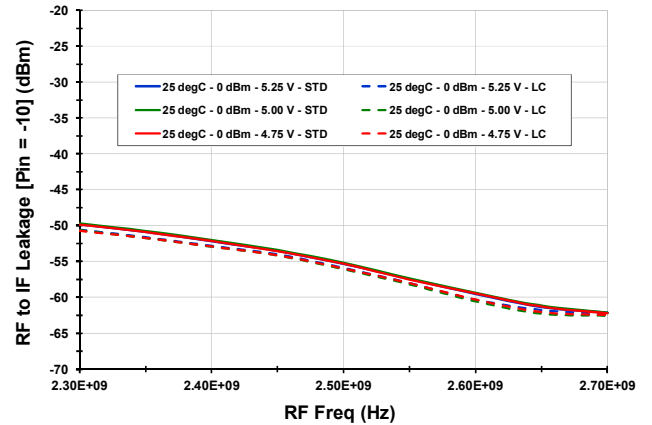
2300 - 2700 MHz F1162NBGI

TYPICAL OPERATING CONDITIONS [IF = 400 MHz, Low Side Injection] (-9-)

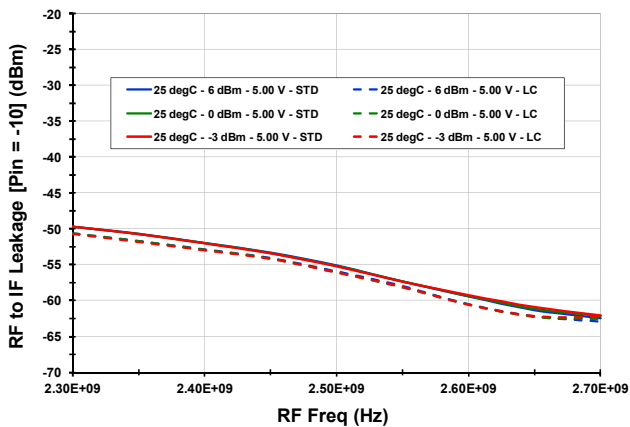
RF-IF Leakage vs. T_{CASE}



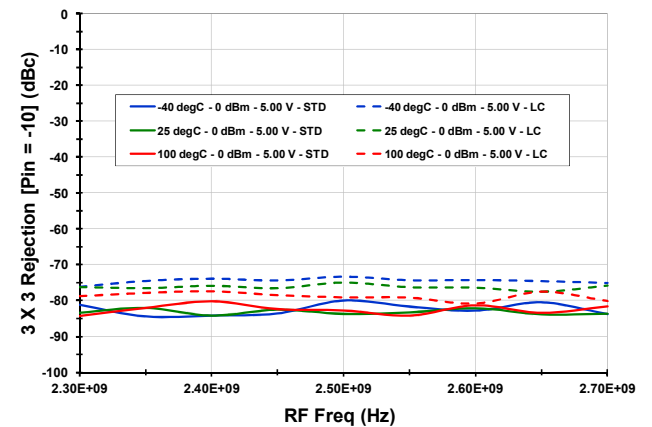
RF-IF Leakage vs. V_{CC}



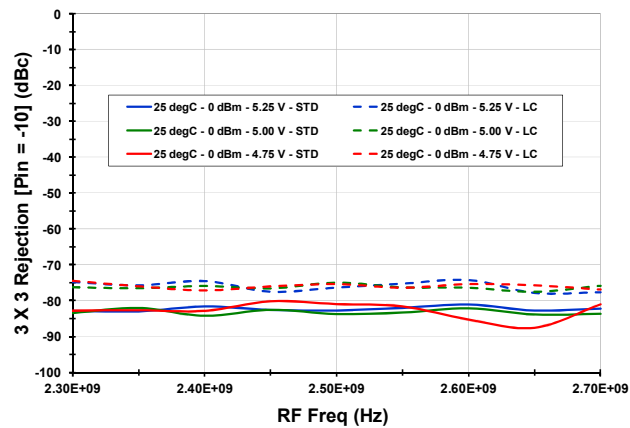
RF-IF Leakage vs. LO Level



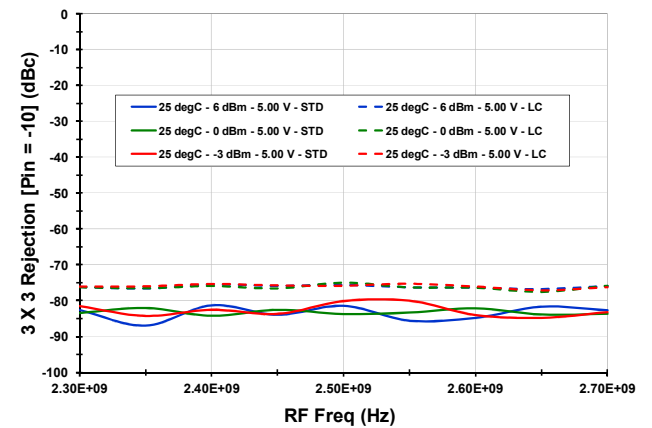
3RF X 3LO Rejection vs. T_{CASE}



3RF X 3LO Rejection vs. V_{CC}

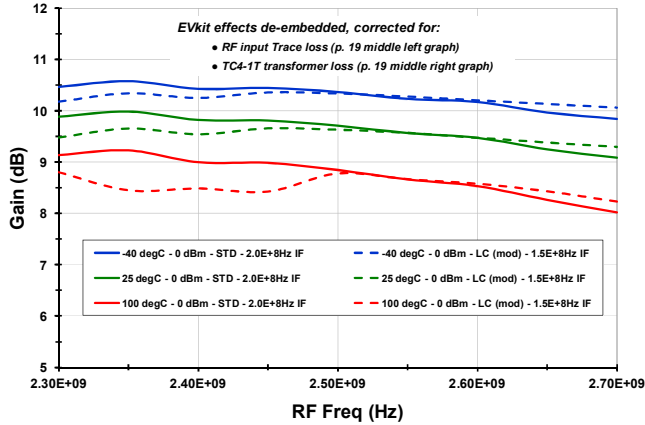


3RF X 3LO Rejection vs. LO Level

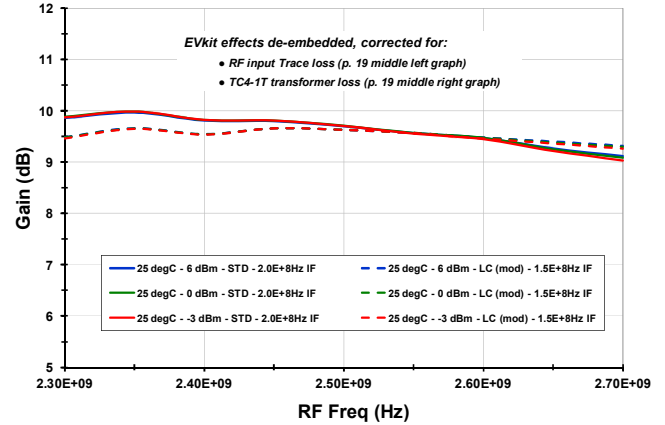


TYPICAL OPERATING CONDITIONS [High Side Injection see LC mode modifications on p. 25] (-10-)

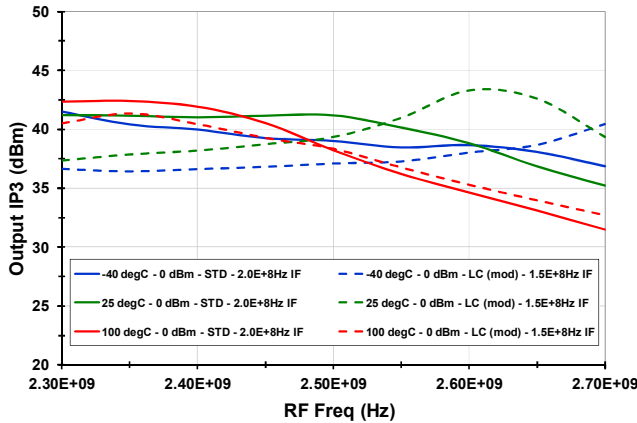
Gain vs. T_{CASE} (EVKIT DE-EMBEDDED)



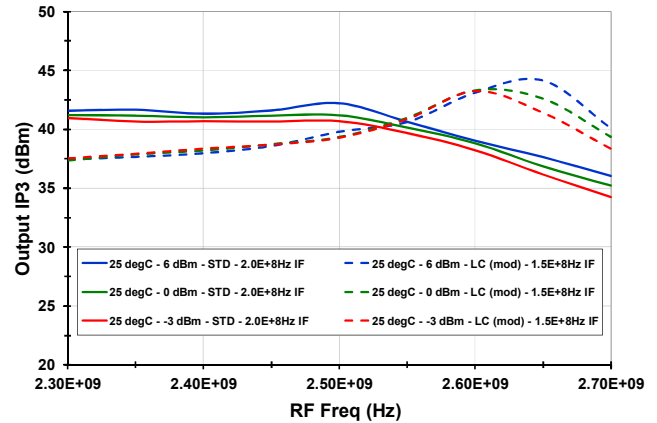
Gain vs. LO Level (EVKit de-embedded)



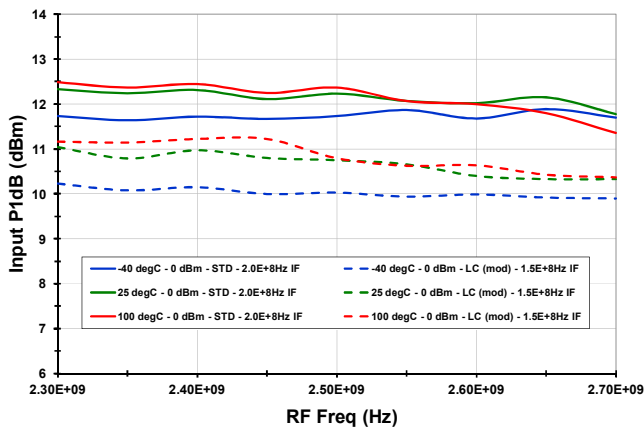
Output IP3 vs. T_{CASE}



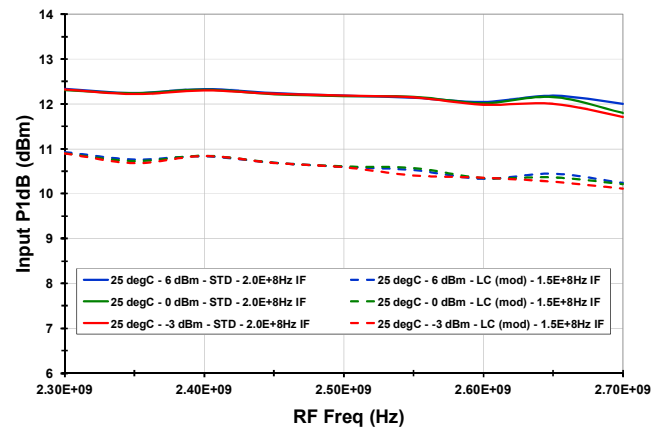
Output IP3 vs. LO Level



P1dB vs. T_{CASE}



P1dB vs. LO Level

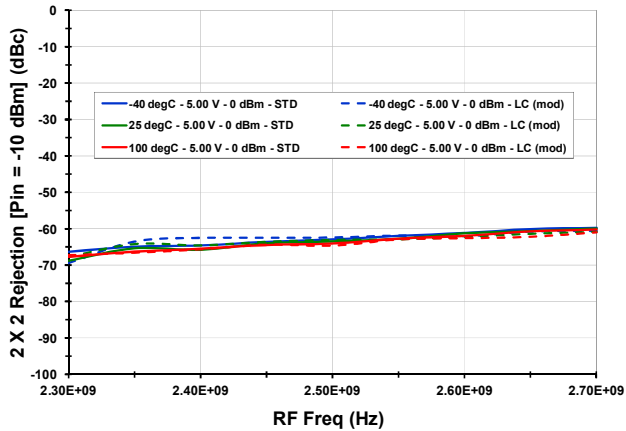


RF to IF Dual Downconverting Mixer

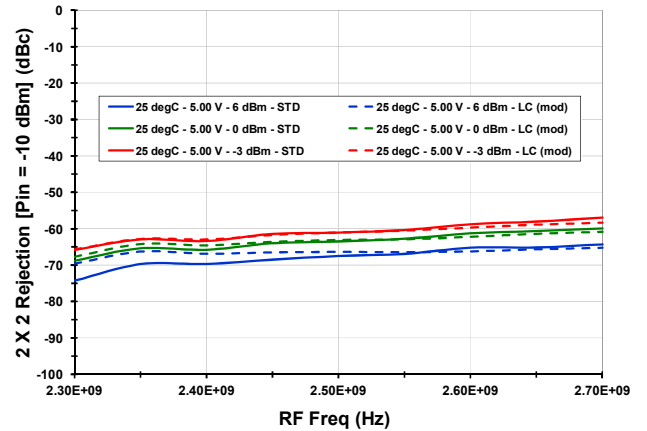
2300 - 2700 MHz F1162NBGI

TYPICAL OPERATING CONDITIONS [High Side Injection see LC mode modifications on p. 25] (-11-)

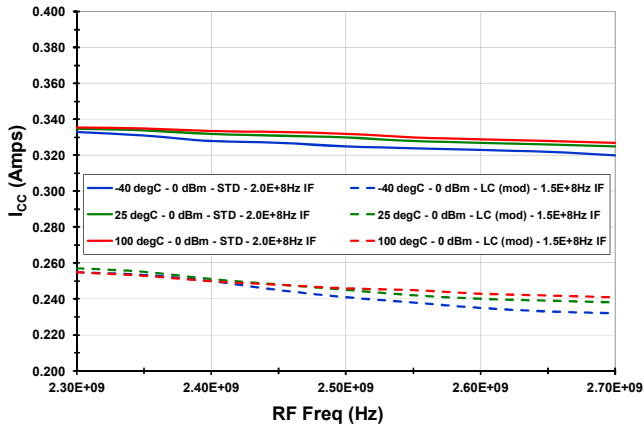
2RF x 2LO vs. T_{CASE} [IF = 154 MHz]



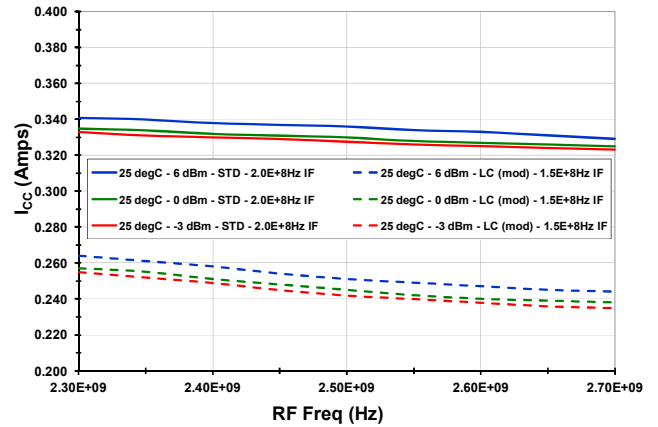
2RF x 2LO vs. LO Level [IF = 154 MHz]



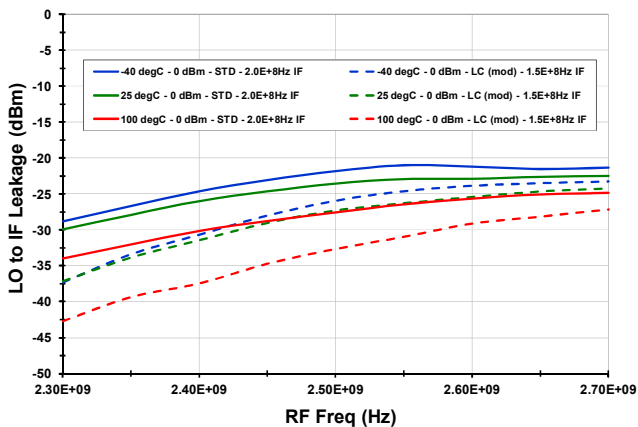
I_{CC} vs. T_{CASE}



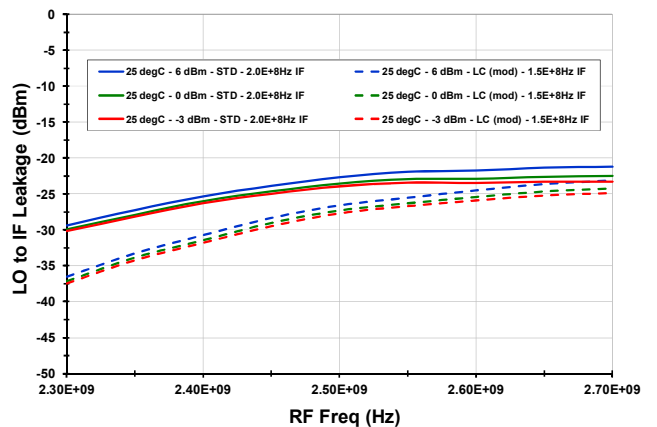
I_{CC} vs. LO Level



LO to IF Leakage vs. T_{CASE}



LO to IF Leakage vs. LO Level

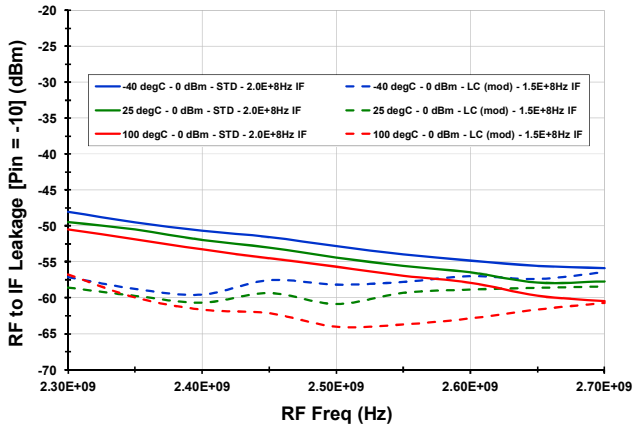


RF to IF Dual Downconverting Mixer

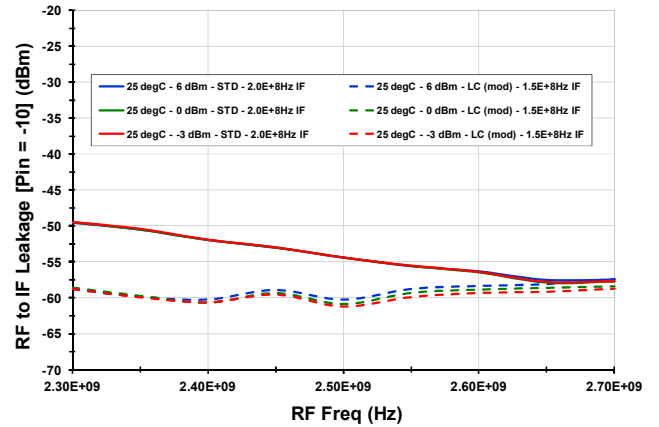
2300 - 2700 MHz F1162NBGI

TYPICAL OPERATING CONDITIONS [High Side Injection see LC mode modifications on p. 25] (-12-)

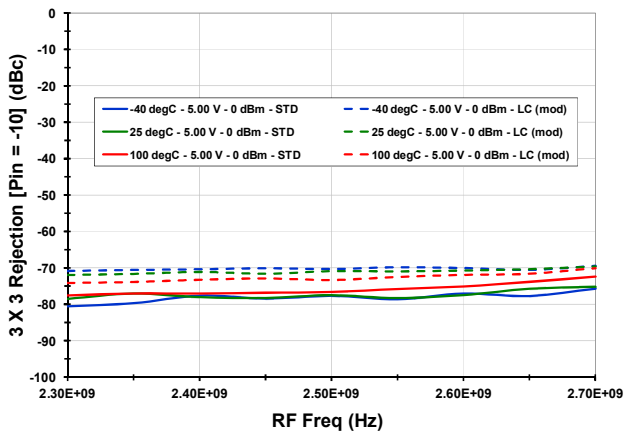
RF to IF Leakage vs. T_{CASE}



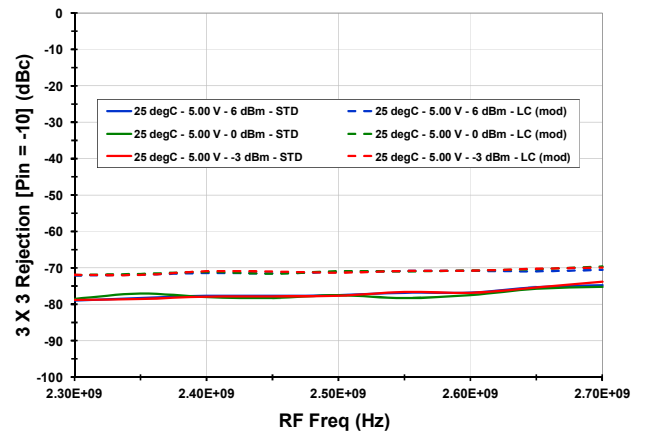
RF to IF Leakage vs. LO Level



3RF x 3LO rejection vs. T_{CASE} [IF = 154 MHz]

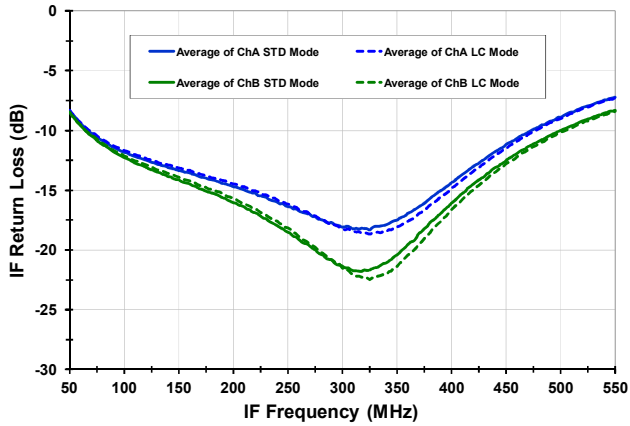


3RF x 3LO rejection vs. LO Level [IF = 154 MHz]

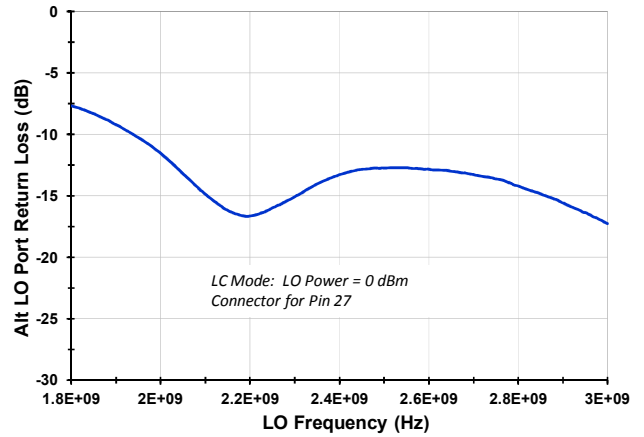


TYPICAL OPERATING CONDITIONS [General] (-13-)

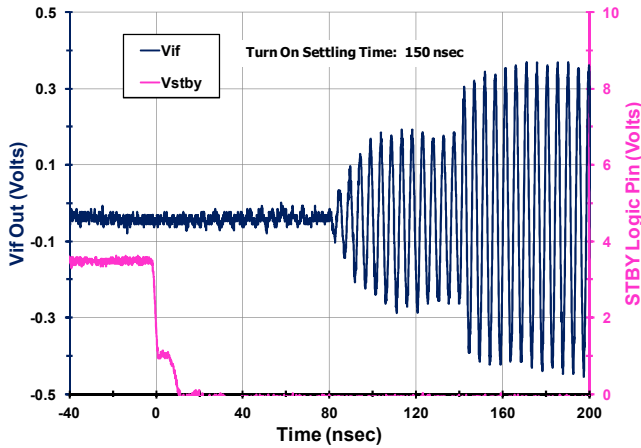
EVkit IF Port Match ($T_A = 25C$)



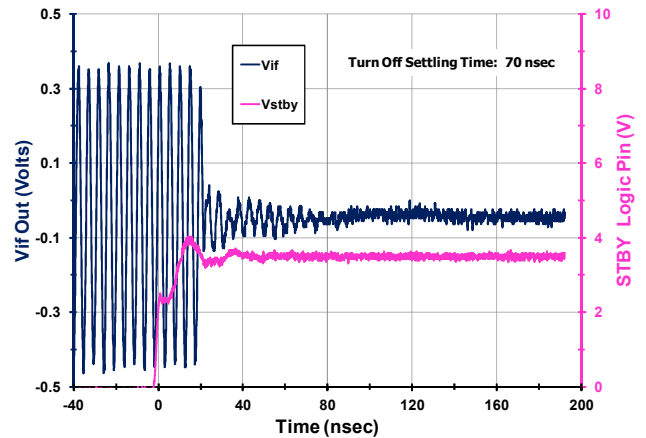
Alt. LO port Match ($T_A = 25C, P_{MEAS} = 0 \text{ dBm}$)



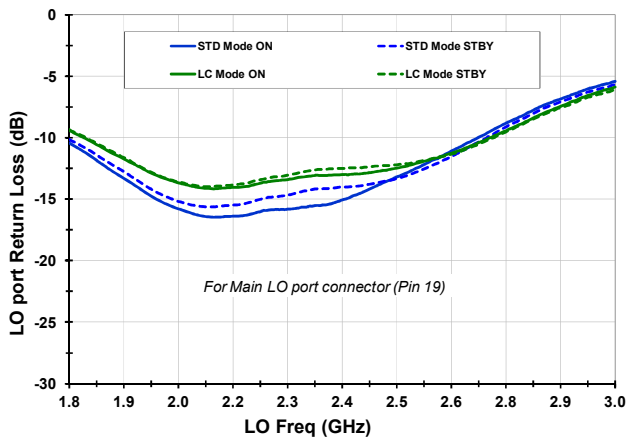
Settling Time (STBY -> V_{IL})



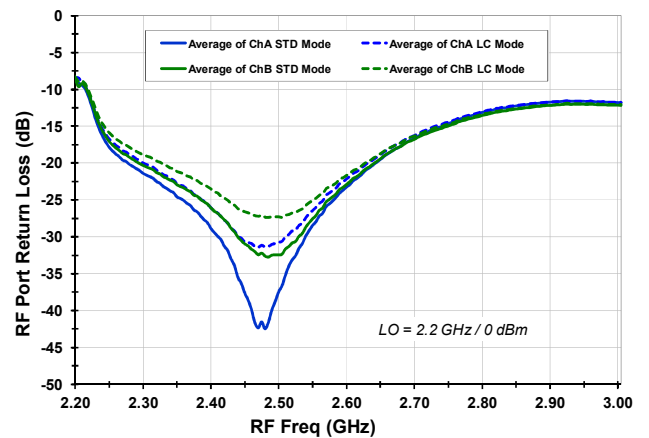
Settling Time (STBY -> V_{IH})



Main LO Port Match ($T_A = 25C, P_{MEAS} = 0 \text{ dBm}$)

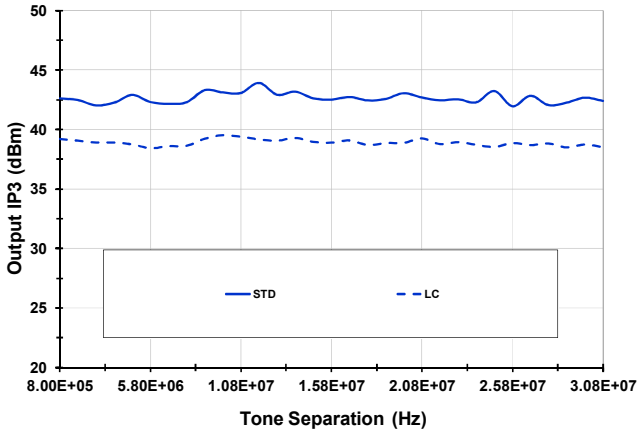


EVkit RF Port Match ($T_A = 25C$)

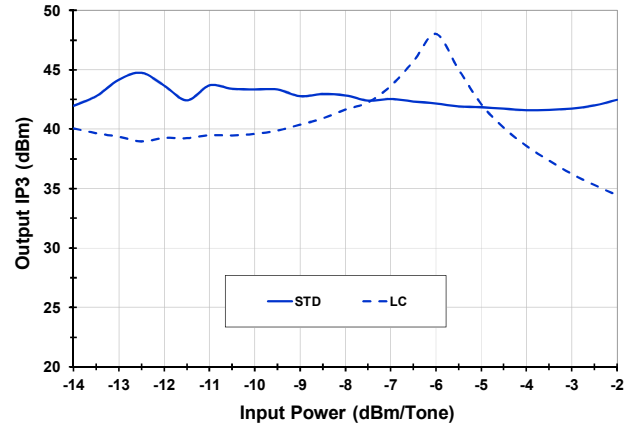


TYPICAL OPERATING CONDITIONS [General] (-14-)

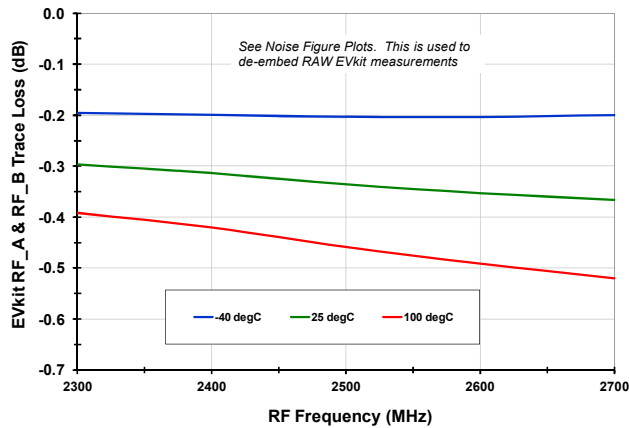
IP_{3O} vs. Δf (T_A = 25C, Freq = 2.6 GHz, IF = 200 MHz)



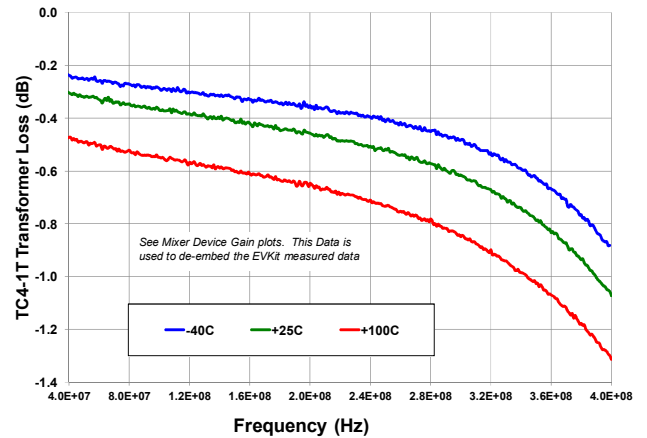
IP_{3O} vs. P_{IN} (T_A = 25C, Freq = 2.6 GHz, IF = 200 MHz)



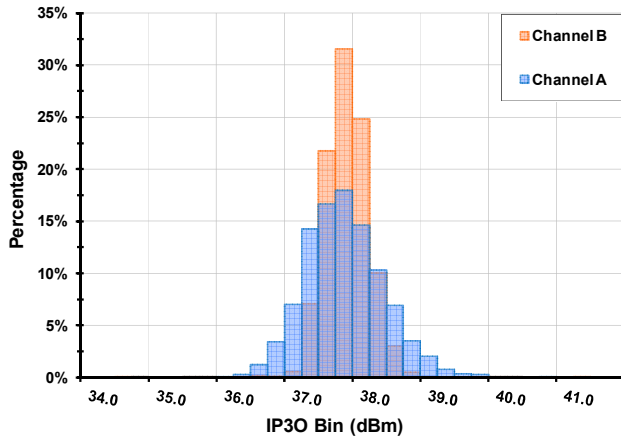
EVkit Input RF Trace Loss (T_A = 25C)



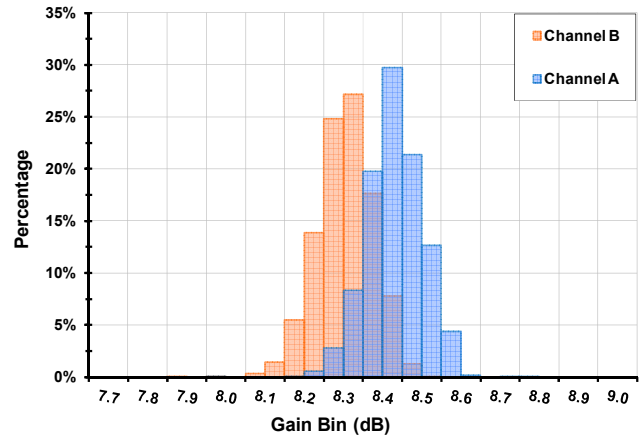
TC4-1T Transformer Loss



IP_{3O} Distribution (F_{IF} = 200MHz, LC mode, N = 3340)



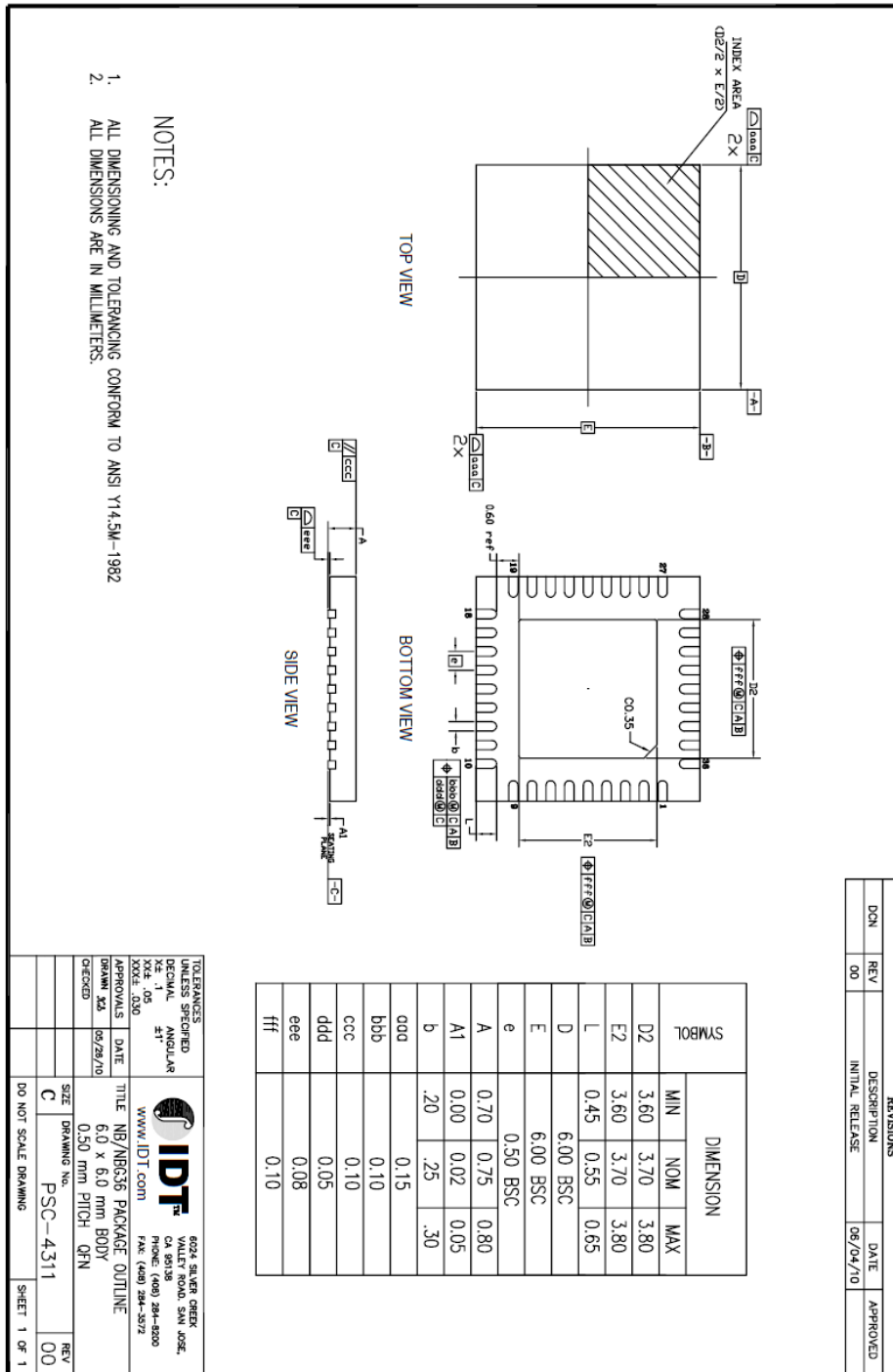
Gain Distribution (F_{IF} = 400MHz, STD mode, N = 3340)



RF to IF Dual Downconverting Mixer

2300 - 2700 MHz F1162NBGI

PACKAGE DRAWING (6X6 QFN)



NOTES:

1. ALL DIMENSIONING AND TOLERANCING CONFORM TO ANSI Y14.5M-1982
2. ALL DIMENSIONS ARE IN MILLIMETERS.

| REVISIONS | | | |
|-----------|-----|-----------------|----------|
| DCN | REV | DESCRIPTION | DATE |
| 00 | 00 | INITIAL RELEASE | 08/04/10 |
| | | | APPROVED |

TOLERANCES UNLESS SPECIFIED DECIMAL ANGULAR ±1°

6024 SILVER BRICK
 10000 WILSON AVENUE, SUITE 1000E
 CA 95135
 PHONE: (408) 284-8500
 FAX: (408) 284-3572
 WWW.IDT.COM

DATE: 08/29/10
 TITLE: NB/NB635 PACKAGE OUTLINE
 6.0 x 6.0 mm BODY
 0.50 mm PITCH QFN

APPROVALS: PSC-4311
 SIZE: C
 DRAWING No.: PSC-4311
 DO NOT SCALE DRAWING

REV: 00
 SHEET: 1 OF 1

RF to IF Dual Downconverting Mixer

2300 - 2700 MHz F1162NBGI

PINOUTS

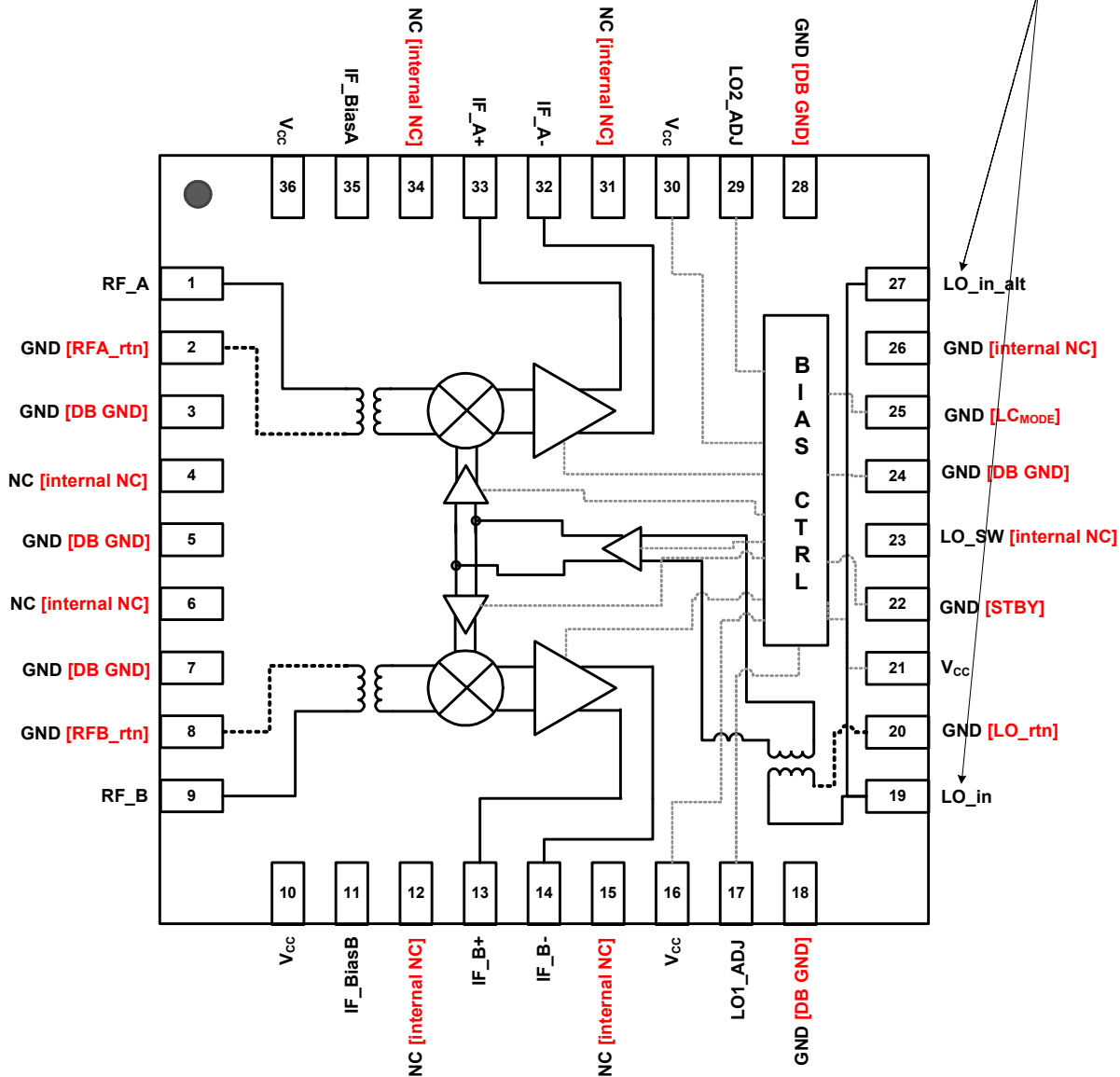
Black Text denotes recommended external connection

Red Text denotes internal Function or Connection

- DB GND = Downbonded to Paddle
- Internal NC = Pin not connected

Please Note!

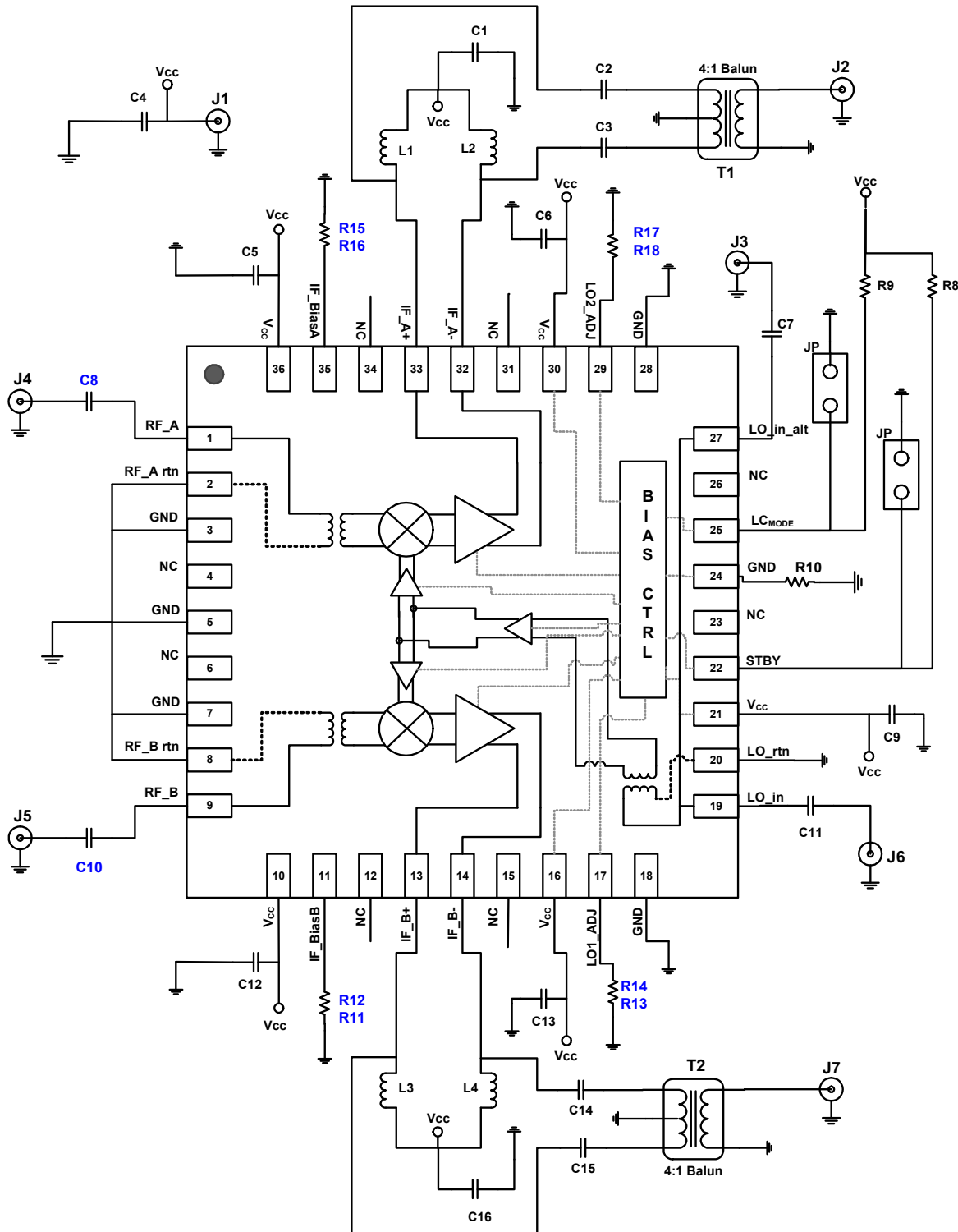
- Only connect to one LO feed
- Choose Either Pin 19 or Pin 27
- Do not connect the unused LO pin to ensure good LO return loss



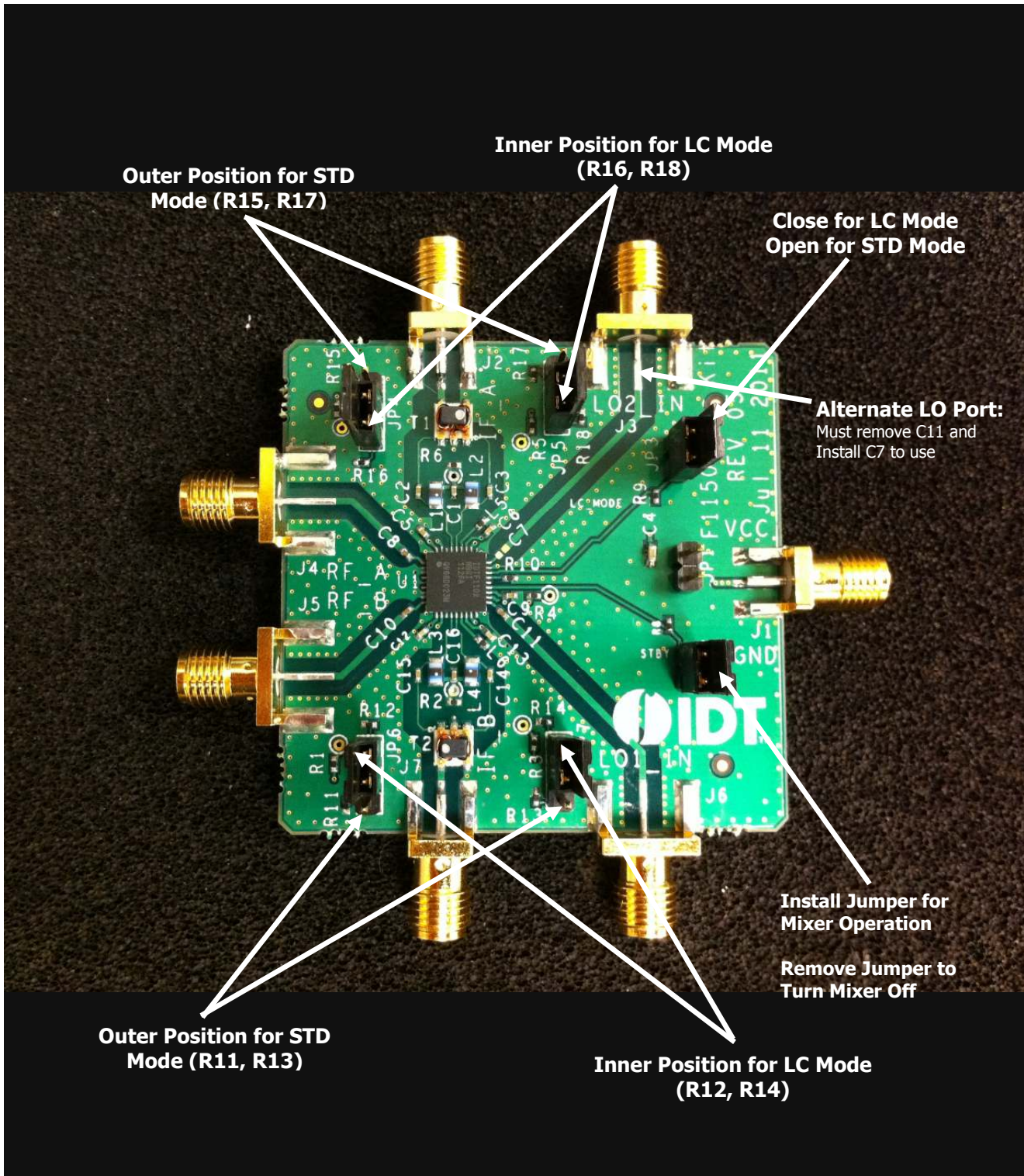
PIN DESCRIPTIONS

| Pin | Name | Function |
|---------------------------------|-----------------------------|--|
| 1 | RF_A | Main Channel RF Input. Internally matched to 50Ω. DO NOT apply DC to these pins |
| 2, 8, 20 | RF_Artn, RF_Brtn, LO_rtn | Transformer Ground Returns. Ground these pins. |
| 3, 5, 7, 18, 24, 28 | GND | Ground these pins. |
| 4, 6, 12, 15, 31, 23, 26, 34 | N.C. | No Connection. Not internally connected. OK to connect to Vcc. OK to connect to GND |
| 10, 16, 21, 30, 36 | VCC | Power Supply. Bypass to GND with capacitors shown in the Typical Application Circuit as close as possible to pin. |
| 9 | RF_B | Diversity Channel RF Input. Internally matched to 50Ω |
| 11 | IF_BiasB | Connect the specified resistor from this pin to ground to set the bias for the Diversity IF amplifier. This is NOT a current set resistor |
| 13, 14 | IFB+, IFB- | Diversity Mixer Differential IF Output. Connect pullup inductors from each of these pins to VCC (see the Typical Application Circuit). |
| 17 | LO1_ADJ | Connect the specified resistor for either Standard or LC mode from this pin to ground to set the LO common buffer Icc |
| 19, 27 | LO_in LO_in_alt | Local Oscillator Input. Connect the LO to this port through the recommended coupling capacitor. Note that you can only drive one LO port at a time. Remove the series capacitor from the unused port. |
| 25 | LC_MODE | Low Current Mode. Set this pin to low or ground for LC mode. Set to high or No-Connect for Standard mode. There is an internal pull-up resistor. |
| 22 | STBY | STBY Mode. Pull this pin high for Standby mode (~20 mA). Pull low or Ground for normal Operation |
| 29 | LO2_ADJ | Connect the specified resistor for either Standard or LC mode from this pin to ground to set the LO drive buffers Icc |
| 32, 33 | IFA-, IFA+ | Main Mixer Differential IF Output. Connect pullup inductors from each of these pins to VCC (see the Typical Application Circuit). |
| 35 | IF_BiasA | Connect the specified resistor from this pin to ground to set the bias for the Main IF amplifier. This is NOT a current set resistor |
| | — EP | Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple via grounds are also required to achieve the noted RF performance. |
| | | |

EVKIT SCHEMATIC



EVKIT PICTURE/LAYOUT/OPERATION



RF to IF Dual Downconverting Mixer
2300 - 2700 MHz F1162NBGI
EVKIT BOM
Default BOM:

For Standard Mode, Open the LC_{MODE} jumper in conjunction with positioning the 4 dual jumpers to select the resistors in **red**.

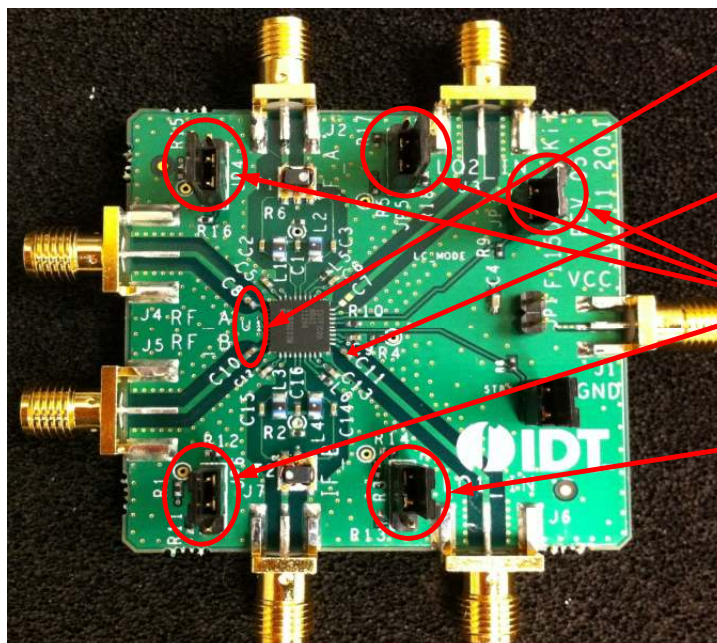
For Low Current Mode close the LC_{MODE} jumper in conjunction with positioning the 4 dual jumpers to select the resistors in **blue**.

F1162 BOM

| Item # | Value | Size | Desc | Mfr. Part # | Mfr. | Part Reference | Qty |
|--------|----------------|--------|---|--------------------|-----------------|-------------------|-----|
| 1 | 10nF | 0402 | CAP CER 1000PF 16V 10% X7R 0402 | GRM155R71C103KA01D | MURATA | C1,5,6,9,12,13,16 | 7 |
| 2 | 1000pF | 0402 | CAP CER 1000PF 50V C0G 0402 | GRM1555C1H102JA01D | MURATA | C2,3,14,15 | 4 |
| 3 | 39pF | 0402 | CAP CER 39PF 50V 5% C0G 0402 | GRM1555C1H390JZ010 | MURATA | C8,10 | 2 |
| 4 | 4.7pF | 0402 | CAP CER 4.7PF 50V 5% C0G 0402 | GRM1555C1H4R7CZ01D | MURATA | C11 | 1 |
| 5 | 1pF | 0402 | Note: C7 and C11 cannot be installed together. C7 for Pin27 LO feed. C11 for Pin19 LO feed | | | C7 | 1 |
| 6 | 10uF | 0603 | CAP CER 10UF 6.3V X5R 0603 | GRM188R60J106ME47D | MURATA | C4 | 1 |
| 7 | Header 2 Pin | TH 2 | CONN HEADER VERT SGL 2POS GOLD | 961102-6404-AR | 3M | JP1,2,3 | 3 |
| 8 | Header 3 Pin | TH 3 | CONN HEADER VERT SGL 3POS GOLD | 961103-6404-AR | 3M | JP4,5,6,7 | 4 |
| 9 | SMA END LAUNCH | .062 | SMA_END_LAUNCH | 142-0711-821 | Emerson Johnson | J1,2,3,4,5,6,7 | 7 |
| 10 | 270nH | 0805 | 0805CS (2012) Ceramic Chip Inductor | 0805CS-271XILB | COILCRAFT | L1,2,3,4 | 4 |
| 11 | 40 | 0402 | RES 40 OHM 1/10W 1% 0402 SMD | ERJ-2RKF40R2X | Panasonic | R11,15 | 2 |
| 12 | 63 | 0402 | RES 63 OHM 1/10W 1% 0402 SMD | ERJ-2RKF62R0X | Panasonic | R12,16 | 2 |
| 13 | 91 | 0402 | RES 91.0 OHM 1/10W 1% 0402 SMD | ERJ-2RKF91R0X | Panasonic | R13 | 1 |
| 14 | 180 | 0402 | RES 180 OHM 1/10W 1% 0402 SMD | ERJ-2RKF1800X | Panasonic | R14 | 1 |
| 15 | 1.91k | 0402 | RES 1.91K OHM 1/10W 1% 0402 SMD | ERJ-2RKF1911X | Panasonic | R18 | 1 |
| 16 | 1.21K | 0402 | RES 1.21K OHM 1/10W 1% 0402 SMD | ERJ-2RKF1211X | Panasonic | R17 | 1 |
| 17 | 47K | 0402 | RES 47.0K OHM 1/16W 1% 0402 SMD | RC0402FR-0747KL | Yageo | R8,9 | 2 |
| 18 | 0 | 0402 | RES 0.0 OHM 1/10W 0402 SMD | ERJ-2GE0R00X | Panasonic | R1,2,3,4,5,6,7,10 | 8 |
| 19 | 4:1 Balun | SM-22 | 4:1 Center Tap Balun | TC4-1TG2+ | Mini Circuits | T1,2 | 2 |
| 20 | F1162 | QFN-36 | Diversity Downconverter | F1162NBGI | IDT | U1 | 1 |
| 21 | PCB | | | F1162 EVKit Rev5 | | | 1 |

Modified BOM (for High Side Injection LC Mode):

EVkit Modifications for High Side Injection Low Current Mode (see TOCs on pages 15 – 17)



- Change C8 and C10 from 39 pF to 4.7 pF
- ↓
- Change C11 from 4.7 pF to 3 pF
- ↓
- Set these 3 Dual Jumpers as shown to INNER position and CLOSE LC_{MODE} Jumper
- ↓
- Set R14/R13 Jumper to OUTER position
- ↓
- Will select 91 ohm resistor for pin17 instead of 180 ohm. All other resistors will be selected for Mode = Low Current

RF to IF Dual Downconverting Mixer

2300 - 2700 MHz F1162NBGI

TOPMARKINGS

